

1 Features

Wireless microcontroller

- Optimized 48MHz Arm[®] Cortex[®]-M0+ processor
- Up to 512KB of in-system programmable flash
- 12KB of ROM for bootloader and drivers
- Up to 64KB of ultra-low leakage SRAM. Full RAM retention in standby mode
- 2.4GHz RF transceiver compatible with Bluetooth[®]
 5.3 Low Energy and IEEE 802.15.4 PHY and MAC
- Integrated balun
- Supports over-the-air upgrade (OTA)
- Serial wire debug (SWD)

Low power consumption

- MCU consumption:
 - 2.6mA active mode, CoreMark®
 - 53µA/MHz running CoreMark[®]
 - < 710nA standby mode on TTC2340R52</p>
 - 165nA shutdown mode, wake-up on pin
 - Radio consumption:
 - 5.3mA RX
 - 5.1mA TX at 0dBm
 - < 11.0mA TX at +8dBm</p>

Wireless protocol support

- Bluetooth® 5.3 Low Energy
- Zigbee®
- Thread
- Proprietary systems

High-performance radio

- –102dBm sensitivity for Bluetooth® Low Energy 125kbps
- –96.5dBm sensitivity for Bluetooth® Low Energy 1Mbps
- –98dBm sensitivity for IEEE 802.15.4 (2.4GHz)
- Output power up to +8dBm with temperature compensation

Regulatory compliance

- Suitable for systems targeting compliance with these standards:
 - EN 300 328 (Europe)
 - FCC CFR47 Part 15
 - ARIB STD-T66 (Japan)

MCU peripherals

- Up to 26 I/O pads
 - 2 IO pads SWD, muxed with GPIOs
 - 2 IO pads LFXT, muxed with GPIOs
 - Up to 22 DIOs (analog or digital IOs)
- Up to 3 × 16-bit and 1× 24-bit general-purpose timers, quadrature decode mode support
- 12-bit ADC, 1.2Msps with external reference, 267ksps with internal reference, up to 12 external ADC inputs
- 1× low power comparator
- 1× UART
- 1× SPI
- 1× I²C
- Real-time clock (RTC)
- Integrated temperature and battery monitor
- Watchdog timer

Security enablers

- AES 128-bit cryptographic accelerator
- Random number generator from on-chip analog noise

Development tools and software

- LP-EM-TTC2340R5 LaunchPad Development Kit
- SimpleLink[™] Low Power F3 software development kit
- SmartRF™ Studio for simple radio configuration
- SysConfig system configuration tool

Operating range

- On-chip buck DC/DC converter
- 1.71V to 3.8V single supply voltage
- T_j: -40°C up to +125°C

RoHS-compliant package

- 5mm × 5mm RKP QFN40
- 4mm × 4mm RGE QFN24



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[™] TTC2340R52 SimpleLink™ Family of 2.4GHz Wireless MCUs

2 Applications

- Medical
 - Home healthcare blood glucose monitors, blood pressure monitor, CPAP machine, electronic thermometer
 - Patient monitoring and diagnostics medical sensor patches
 - Personal care and fitness electric toothbrush, wearable fitness & activity monitor
- Building automation
 - Building security systems motion detector, electronic smart lock, door and window sensor, garage door system, gateway
 - HVAC thermostat, wireless environmental sensor
 - Fire safety system smoke and heat detector
 - Video surveillance IP network camera
- Lighting
 - LED luminaire
 - Lighting control daylight sensor, lighting sensor, wireless control
- Factory automation and control

- Retail automation & payment electronic point of sale
 - Electronic shelf label
- Grid infrastructure
 - Smart meters water meter, gas meter, electricity meter, and heat cost allocators
 - Grid communications wireless communications – Long-range sensor applications
- Other alternative energy energy harvesting
- Communication equipment
 - Wired networking
 - wireless LAN or Wi-Fi access points, edge router
- Personal electronics
 - Connected peripherals consumer wireless module, pointing devices, keyboards and keypads
 - Gaming electronic and robotic toys
 - Wearables (non-medical) smart trackers, smart clothing

3 Description

The TTC2340R SimpleLink[™] family of devices are 2.4GHz wireless microcontrollers (MCUs), targeting Bluetooth® 5.3 Low Energy, Zigbee, Thread, and Proprietary 2.4GHz applications. These devices are optimized for low-power wireless communication with Over the Air Download (OAD) support in Building automation (wireless sensors, lighting control, beacons), asset tracking, medical, retail EPOS (electronic point of sale), ESL (electronic shelf), and Personal electronics (toys, HID, stylus pens) markets. Highlighted features of this device include:

- Support for Bluetooth 5 features: high-speed mode (2Mbps PHY), long-range (LE Coded 125kbps and 500kbps PHYs), privacy 1.2.1 and channel selection algorithm #2, as well as backward compatibility and support for key features from the Bluetooth 4.2 and earlier Low Energy specifications.
- Fully qualified Bluetooth 5.3 software protocol stack included with the SimpleLink[™] Low Power F3 software development kit (SDK)
- Zigbee® protocol stack support in the SimpleLink™ Low Power F3 software development kit (SDK)
- Thread protocol stack support in SIMPLELINK TI OPENTHREAD SDK ⁽¹⁾
- Ultra-low standby current less than 0.71µA with RTC operational and full RAM retention that enables significant battery life extension, especially for applications with longer sleep intervals.
- Integrated balun for reduced bill-of-material (BOM) board layout
- Excellent radio sensitivity and robustness (selectivity and blocking) performance for Bluetooth Low Energy (-102dBm for 125kbps LE Coded PHY, with integrated balun)

The TTC2340R family is part of the SimpleLink[™] MCU platform, which consists of Wi-Fi[®], Bluetooth Low Energy, Thread, Zigbee, Sub-1GHz MCUs, and host MCUs that all share a common, easy-to-use development environment with a single-core software development kit (SDK) and rich tool set. A one-time integration of the SimpleLink[™] platform enables you to add any combination of the portfolio's devices into your design, allowing 100 percent code reuse when your design requirements change. For more information, visit the SimpleLink[™] MCU platform.

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[₹] TTC2340R52 SimpleLink™ Family of 2.4GHz Wireless MCUs

Device Information

PART NUMBER ⁽²⁾	FLASH	RAM	TEMPERATURE RANGE	PACKAGE	STATUS			
TTC2340R52E0RKPR	512KB	36KB	–40°C–125°C	QFN40	Released			
TTC2340R52E0RGER	512KB	36KB	–40°C–125°C	QFN24	Released			

(1) Available in a future release

(2) For more information, see Section 12.

4 Functional Block Diagram

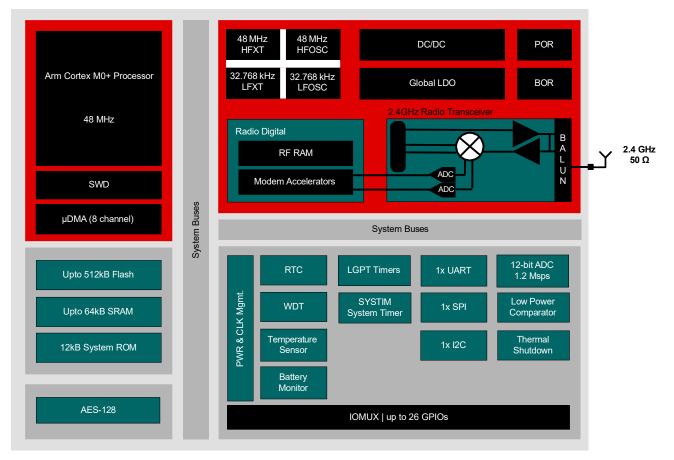


Figure 4-1. TTC2340R Family Block Diagram



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5 Device Comparison

	RADIO SUPPORT						PACKAGE SIZE			
Device	2.4GHz Prop.	Bluetooth® LE	ZigBee	Thread	FLASH (KB)	RAM + Cache (KB)	gpio		4 X 4 mm VQFN (24)	5 X 5 mm VQFN (40)
TTC2340R52	\checkmark	\checkmark	\checkmark	\checkmark	512	36	12-26		\checkmark	\checkmark



6 Pin Configurations and Functions

6.1 Pin Diagrams

6.1.1 Pin Diagram—RKP Package (Top View)

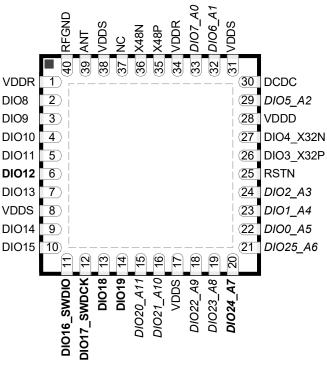


Figure 6-1. RKP (5mm × 5mm) Pinout, 0.4mm Pitch (Top View)

The following I/O pins marked in Figure 6-1 in **bold** have high-drive capabilities:

- Pin 6, DIO12
- Pin 11, DIO16_SWDIO
- Pin 12, DIO17_SWDCK
- Pin 13, DIO18
- Pin 14, DIO19
- Pin 20, DIO24_A7

The following I/O pins marked in Figure 6-1 in *italics* have analog capabilities:

- Pin 15, DIO20_A11
- Pin 16, DIO21_A10
- Pin 18, DIO22_A9
- Pin 19, DIO23_A8
- Pin 20, DIO24 A7
- Pin 21, DIO25 A6
- Pin 22, DIO0 A5
- Pin 23, DIO1_A4
- Pin 24, DIO2_A3
- Pin 29, DIO5_A2
- Pin 32, DIO6, A1
- Pin 33, DIO7_A0



6.1.2 Pin Diagram – RGE Package (Top View)

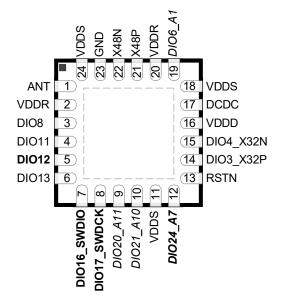


Figure 6-2. RGE (4mm × 4mm) Pinout, 0.5mm Pitch (Top View)

The following I/O pins marked in Figure 6-2 in **bold** have high-drive capabilities:

- Pin 5, DIO12
- Pin 7, DIO16_SWDIO
- Pin 8, DIO17_SWDCK
- Pin 12, DIO24_A7

The following I/O pins marked in Figure 6-2 in *italics* have analog capabilities:

- Pin 9, DIO20_A11
- Pin 10, DIO21_A10
- Pin 12, DIO24_A7
- Pin 19, DIO6_A1



RKP PIN NUMBER	RGE PIN NUMBER SIGNAL NAME		PIN NAME MUX ENCODING		SIGNAL TYPE	
39	1	ANT	ANT		RF	
30	17	DCDC	DCDC		PWR	

Table 6-1. Pin Attributes (RKP, RGE, YBG, Packages)



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	Table 6-1. Pin Attributes (RKP, RGE, YBG, Packages) (continued)								
RKP PIN NUMBER	RGE PIN NUMBER	SIGNAL NAME	PIN NAME	MUX ENCODING	SIGNAL TYPE				
2	3	DIO8	GPIO8	0	I/O				
			SPI0SCLK	1	I/O				
			UART0RTS	2	I/O				
			T1C0N	3	I/O				
			I2C0SDA	4	I/O				
			TOCON	5	I/O				
			DTB3	7	I/O				
3		DIO9	GPIO9	0	I/O				
			T3C0	1	I/O				
			LRFD3	3	I/O				
22		DIO0_A5	GPIO0	0	I/O				
			SPIOCSN	1	I/O				
			I2C0SDA	2	I/O				
			T3C2	3	I/O				
			ANA5	6	ANALOG				
4		DIO10	GPIO10	0	I/O				
			LPCO	1	I/O				
			T2PE	2	I/O				
			T3C0N	3	I/O				
5	4	DIO11	GPIO11	0	I/O				
			SPIOCSN	1	I/O				
			T1C2N	2	I/O				
			T0C0	3	I/O				
			LRFD0	4	I/O				
			SPI0POCI	5	I/O				
			DTB9	7	I/O				
6	5	DIO12	GPIO12	0	I/O				
			SPI0POCI	1	I/O				
			SPI0PICO	2	I/O				
			UART0RXD	3	I/O				
			T1C1	4	I/O				
			I2C0SDA	5	I/O				
			DTB13	7	I/O				
7	6	DIO13	GPIO13	0	I/O				
			SPI0POCI	1	I/O				
			SPI0PICO	2	I/O				
			UART0TXD	3	I/O				
			T0C0N	4	I/O				
			T1F	5	I/O				
			DTB4	7	I/O				



RKP PIN NUMBER	RGE PIN NUMBER	SIGNAL NAME	PIN NAME	MUX ENCODING	SIGNAL TYPE
9		DIO14	GPIO14	0	I/O
			T3C2	1	I/O
			T1C2N	2	I/O
			LRFD5	3	I/O
			T1F	4	I/O
10		DIO15	GPIO15	0	I/O
			UARTORXD	1	I/O
			T2C0N	2	I/O
			CKMIN	3	I/O
11	7	DIO16_SWDIO	GPIO16	0	I/O
			SPIOPICO	1	I/O
			UARTORXD	2	I/O
			I2C0SDA	3	I/O
			T1C2	4	I/O
			T1C0N	5	I/O
			DTB10	7	I/O
12	8	DIO17_SWDCK	GPIO17	0	I/O
			SPIOSCLK	1	I/O
			UART0TXD	2	I/O
			I2C0SCL	3	I/O
			T1C1N	4	I/O
			T0C2	5	I/O
			DTB11	7	I/O
13		DIO18	GPIO18	0	I/O
			T3C0	1	I/O
			LPCO	2	I/O
			UART0TXD	3	I/O
			SPIOSCLK	4	I/O
			DTB12	7	I/O
14		DIO19	GPIO19	0	I/O
			T3C1	1	I/O
			T2PE	2	I/O
			SPI0PICO	4	I/O
			DTB0	7	I/O
23		DIO1_A4	GPIO1	0	I/O
			T3C1	1	I/O
			LRFD7	2	I/O
			T1F	3	I/O
			UART0RTS	4	I/O
			ANA4	6	ANALOG
			DTB2	7	I/O

Table 6-1. Pin Attributes (RKP, RGE, YBG, Packages) (continued)



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AL NAME A11		MUX ENCODING	SIGNAL TYPE
<u>A</u> 11	CDI020		
	GPIO20	0	I/O
	LPCO	1	I/O
	UART0TXD	2	I/O
	UART0RXD	3	I/O
	T1C0	4	I/O
	SPI0POCI	5	I/O
	ANA11	6	ANALOG
	DTB14	7	I/O
A10	GPIO21	0	I/O
	UART0CTS	1	I/O
	T1C1N	2	I/O
	T0C1	3	I/O
	SPI0POCI	4	I/O
	LRFD1	5	I/O
	ANA10	6	ANALOG
	DTB15	7	I/O
A9	GPIO22	0	I/O
	T2C0N	1	I/O
	UARTORXD	2	I/O
	T3C1N	3	I/O
	ANA9	6	ANALOG
	DTB1	7	I/O
A8	GPIO23	0	I/O
	T2C1	1	I/O
	T3C2N	3	I/O
	ANA8	6	ANALOG
A7	GPIO24	0	I/O
•	SPI0SCLK	1	I/O
	T1C0	2	I/O
	T3C0	3	I/O
	TOPE	4	I/O
	I2C0SCL	5	I/O
	ANA7	6	ANALOG
	DTB5	7	I/O
16	GPIO25	0	I/O
	SPI0POCI	1	I/O
	I2C0SCL	2	I/O
	T2C2N	3	I/O
		6	ANALOG
.3			I/O
			ANALOG
7	43	ANA6 A3 GPIO2 T0PE T2C1N UART0CTS ANA3	A3 GPIO2 0 T0PE 1 T2C1N 2 UART0CTS 3



RKP PIN NUMBER	RGE PIN NUMBER	SIGNAL NAME	PIN NAME	MUX ENCODING	SIGNAL TYPE
26	14	DIO3_X32P	GPIO3	0	I/O
			LFCI	1	I/O
			T0C1N	2	I/O
			LRFD0	3	I/O
			T3C1	4	I/O
			T1C2	5	I/O
			LFXT_P	6	I/O
			DTB7	7	I/O
27	15	DIO4_X32N	GPIO4	0	I/O
			T0C2N	1	I/O
			UART0TXD	2	I/O
			LRFD1	3	I/O
			SPI0PICO	4	I/O
			T0C2	5	I/O
			LFXT_N	6	I/O
			DTB8	7	I/O
29		DIO5_A2	GPIO5	0	I/O
			T2C2	1	I/O
			LRFD6	3	I/O
			ANA2	6	ANALOG
32	19	DIO6_A1	GPIO6	0	I/O
			SPIOCSN	1	I/O
			I2C0SCL	2	I/O
			T1C2	3	I/O
			LRFD2	4	I/O
			UART0TXD	5	I/O
			ANA1	6	ANALOG
			DTB6	7	I/O
33		DIO7_A0	GPIO7	0	I/O
			T3C1	1	I/O
			LRFD4	3	I/O
			ANA0	6	ANALOG
	23	GND	GND		GND
37		NC	NC		NC
40		RFGND	RFGND		GND
25	13	RSTN	RSTN		I/O
28	16	VDDD	VDDD		PWR
1, 34	2, 20	VDDR	VDDR		PWR
17, 31, 38, 8	11, 18, 24	VDDS	VDDS		PWR
36	22	X48N	X48N		I/O
35	21	X48P	X48P		I/O

Table 6-1. Pin Attributes (RKP, RGE, YBG, Packages) (continued)



6.2 Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
ANA0	ANALOG	1	ADC reference (negative terminal) or ADC channel 0 input	33	
ANA1	ANALOG	1	ADC reference (positive terminal) or ADC channel 1 input	32	19
ANA2	ANALOG	I	ADC channel 2 input	29	
ANA3	ANALOG	I	ADC channel 3 input	24	
ANA4	ANALOG	I	ADC channel 4 input	23	
ANA5	ANALOG	I	ADC channel 5 input	22	
ANA6	ANALOG	I	ADC channel 6 input	21	
ANA7	ANALOG	1	Low power comparator input (positive terminal) / ADC channel 7 input	20	12
ANA8	ANALOG	1	Low power comparator input (positive or negative terminal) / ADC channel 8 input	19	
ANA9	ANALOG	I	ADC channel 9 input	18	
ANA10	ANALOG	1	Low power comparator input (positive terminal) / ADC channel 10 input	16	10
ANA11	ANALOG	I	ADC channel 11 input	15	9

Table 6-2. Analog Input Signal Descriptions

Table 6-3. Clock Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
CKMIN	I/O	I	HFOSC tracking loop input	10	
LFCI	I/O	I	Low frequency clock input (LFXT bypass clock from pin)	26	14
LFXT_N	I/O	I	32kHz crystal oscillator pin 2	27	15
LFXT_P	I/O	I	32kHz crystal oscillator pin 1	26	14
X48N	I/O	I	48MHz crystal oscillator pin 2	36	22
X48P	I/O	I	48MHz crystal oscillator pin 1	35	21

Table 6-4. DTB Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
DTB0	I/O	0	Digital test bus output 0	14	
DTB1	I/O	0	Digital test bus output 1	18	
DTB2	I/O	0	Digital test bus output 2	23	
DTB3	I/O	0	Digital test bus output 3	2	3
DTB4	I/O	0	Digital test bus output 4	7	6
DTB5	I/O	0	Digital test bus output 5	20	12
DTB6	I/O	0	Digital test bus output6	32	19
DTB7	I/O	0	Digital test bus output 7	26	14
DTB8	I/O	0	Digital test bus output 8	27	15
DTB9	I/O	0	Digital test bus output 9	5	4
DTB10	I/O	0	Digital test bus output 10	11	7



SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
DTB11	I/O	0	Digital test bus output 11	12	8
DTB12	I/O	0	Digital test bus output 12	13	
DTB13	I/O	0	Digital test bus output 13	6	5
DTB14	I/O	0	Digital test bus output 14	15	9
DTB15	I/O	0	Digital test bus output 15	16	10

Table 6-4. DTB Signal Descriptions (continued)

Table 6-5. GPIO Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
GPIO0	I/O	I/O	General-purpose input or output	22	
GPIO1	I/O	I/O	General-purpose input or output	23	
GPIO2	I/O	I/O	General-purpose input or output	24	
GPIO3	I/O	I/O	General-purpose input or output	26	14
GPIO4	I/O	I/O	General-purpose input or output	27	15
GPIO5	I/O	I/O	General-purpose input or output	29	
GPIO6	I/O	I/O	General-purpose input or output	32	19
GPIO7	I/O	I/O	General-purpose input or output	33	
GPIO8	I/O	I/O	General-purpose input or output	2	3
GPIO9	I/O	I/O	General-purpose input or output	3	
GPIO10	I/O	I/O	General-purpose input or output	4	
GPIO11	I/O	I/O	General-purpose input or output	5	4
GPIO12	I/O	I/O	General-purpose input or output	6	5
GPIO13	I/O	I/O	General-purpose input or output	7	6
GPIO14	I/O	I/O	General-purpose input or output	9	
GPIO15	I/O	I/O	General-purpose input or output	10	
GPIO16	I/O	I/O	General-purpose input or output	11	7
GPIO17	I/O	I/O	General-purpose input or output	12	8
GPIO18	I/O	I/O	General-purpose input or output	13	
GPIO19	I/O	I/O	General-purpose input or output	14	
GPIO20	I/O	I/O	General-purpose input or output	15	9
GPIO21	I/O	I/O	General-purpose input or output	16	10
GPIO22	I/O	I/O	General-purpose input or output	18	
GPIO23	I/O	I/O	General-purpose input or output	19	
GPIO24	I/O	I/O	General-purpose input or output	20	12
GPIO25	I/O	I/O	General-purpose input or output	21	

Table 6-6. Device Grounds

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
GND	GND	N/A	Ground		23
RFGND	GND	N/A	RF ground reference	40	

Table 6-7. I²C Signal Descriptions

12C0SCL 1/O 1/O 1/C 12C clock 12, 20, 21, 32 12, 19, 8	SIGNAL NAM		SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
	12C0SCL	I/O	I/O	I2C clock	12, 20, 21, 32	12, 19, 8

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Product Folder Links: TTC2340R2



Table 6-7. I²C Signal Descriptions (continued)

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
I2C0SDA	I/O	I/O	I2C data	11, 2, 22, 6	3, 5, 7

Table 6-8. Low Power Comparator Output Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
LPCO	I/O	0	Low power comparator output	13, 15, 4	9

Table 6-9. No Connect

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
NC	NC	N/A	No connect	37	

Table 6-10. Device Power

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
DCDC ⁽¹⁾	PWR	N/A	Switch node of the internal DC/DC converter	30	17
VDDD ⁽¹⁾	PWR	N/A	Internal 1.28V regulator decoupling capacitor	28	16
VDDR	PWR	N/A	Internal supply, must be powered from the internal DC/DC converter or the internal LDO	1, 34	2, 20
VDDS	PWR	N/A	1.71V to 3.8V supply	17, 31, 38, 8	11, 18, 24

(1) Do not supply external circuitry from this pin.

Table 6-11. Reset Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
RSTN	I/O	I	Global main device reset (active low)	25	13

Table 6-12. Radio Digital Output Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
LRFD0	I/O	0	Radio Core Output 0	26, 5	14, 4
LRFD1	I/O	0	Radio Core Output 1	16, 27	10, 15
LRFD2	I/O	0	Radio Core Output 2	32	19
LRFD3	I/O	0	Radio Core Digital Output 3	3	
LRFD4	I/O	0	Radio Core Output 4	33	
LRFD5	I/O	0	Radio Core Output 5	9	
LRFD6	I/O	0	Radio Core Output 6	29	
LRFD7	I/O	0	Radio Core Output 7	23	

Table 6-13. RF Port

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
ANT	RF	I/O	50Ω RF port	39	1



Table 6-14. SPI Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
SPI0CSN	I/O	I/O	SPI chip select	22, 32, 5	19, 4
SPI0PICO	I/O	I/O	SPI peripheral in controller out	11, 14, 27, 6, 7	15, 5, 6, 7
SPI0POCI	I/O	I/O	SPI peripheral out controller in	15, 16, 21, 5, 6, 7	10, 4, 5, 6, 9
SPI0SCLK	I/O	I/O	SPI clock	12, 13, 2, 20	12, 3, 8

Table 6-15. Timers Capture or Compare Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
TOCO	I/O	I/O	Capture or compare 0 from timer 0	5	4
T0C1	I/O	I/O	Capture or compare 1 from timer 0	16	10
T0C2	I/O	I/O	Capture or compare 2 from timer 0	12, 27	15, 8
T1C0	I/O	I/O	Capture or compare 0 from timer 1	15, 20	12, 9
T1C1	I/O	I/O	Capture or compare 1 from timer 1	6	5
T1C2	I/O	I/O	Capture or compare 2 from timer 1	11, 26, 32	14, 19, 7
T2C1	I/O	I/O	Capture or compare 1 from timer 2	19	
T2C2	I/O	I/O	Capture or compare 2 from timer 2	29	
T3C0	I/O	I/O	Capture or compare 0 from timer 3	13, 20, 3	12
T3C1 ⁽¹⁾	I/O	I/O	Capture or compare 1 from timer 3	14, 23, 26, 33	14
T3C2	I/O	I/O	Capture or compare 2 from timer 3	22, 9	

(1) Timer 3 not available on TTC2340R21.

Table 6-16. Timers Complementary Output Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
TOCON	I/O	0	Complementary compare or PWM output 0 from timer 0	2, 7	3, 6
T0C1N	I/O	0	Complementary compare or PWM output 1 from timer 0	26	14
T0C2N	I/O	0	Complementary compare or PWM output 2 from timer 0	27	15
T1C0N	I/O	0	Complementary compare or PWM output 0 from timer 1	11, 2	3, 7
T1C1N	I/O	0	Complementary compare or PWM output 1 from timer 1	12, 16	10, 8
T1C2N	I/O	0	Complementary compare or PWM output 2 from timer 0	5, 9	4
T2C0N	I/O	0	Complementary compare or PWM output 0 from timer 2	10, 18	
T2C1N	I/O	0	Complementary compare or PWM output 1 from timer 2	24	

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SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN	
T2C2N	I/O	0	Complementary compare or PWM output 2 from timer 2	21		
T3C0N	I/O	0	Complementary compare or PWM output 0 from timer 3	4		
T3C1N	I/O	0	Complementary compare or PWM output 1 from timer 3	18		
T3C2N	I/O	0	Complementary compare or PWM output 2 from timer 3	19		

Table 6-16. Timers Complementary Output Signal Descriptions (continued)

Table 6-17. Timers Fault Input Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
T1F	I/O	I	Fault input for timer 1	23, 7, 9	6

Table 6-18. Timers Prescaler Event Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
TOPE	I/O	0	Prescaler event output from timer 0	20, 24	12
T2PE	I/O	0	Prescaler event output from timer 2	14, 4	

Table 6-19. UART Signal Descriptions

SIGNAL NAME	PIN TYPE	SIGNAL DIRECTION	DESCRIPTION	RKP PIN	RGE PIN
UART0CTS	I/O	I	UART clear-to-send input (active low)	16, 24	10
UART0RTS	I/O	0	UART request-to-send (active low)	2, 23	3
UART0RXD	I/O	I	UART receive data	10, 11, 15, 18, 6	5, 7, 9
UART0TXD	I/O	0	UART transmit data	12, 13, 15, 27, 32, 7	15, 19, 6, 8, 9

6.3 Connections for Unused Pins and Modules

Table 6-20. Connections for Unused Pins

FUNCTION	SIGNAL NAME	ACCEPTABLE PRACTICE ⁽¹⁾	PREFERRED PRACTICE ⁽¹⁾
GPIO (digital)	DIOn	NC, GND, or VDDS	NC
SWD	DIO16_SWDIO	NC, GND, or VDDS	GND or VDDS
	DIO17_SWDCK	NC, GND, or VDDS	GND or VDDS
GPIO (digital or analog)	DIOn_Am	NC, GND, or VDDS	NC
32.768-kHz crystal	DIO3_X32P	NC or GND	NC
	DIO4_X32N		NC .
DC/DC converter ⁽²⁾	DCDC	NC	NC
	VDDS	VDDS	VDDS

(1) NC = No connect

(2) When the DC/DC converter is not used, the inductor between DCDC and VDDR can be removed. VDDR must still be connected and the 10µF DCDC capacitor must be kept on the VDDR net.



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

		MIN	MAX	UNIT
VDDS	Supply voltage	-0.3	4.1	V
	Voltage on any digital pin ⁽³⁾	-0.3	VDDS + 0.3, max 4.1	V
	Voltage on crystal oscillator pins X48P and X48N	-0.3	1.24	V
V _{in_adc}	Voltage on ADC input	0	VDDS	V
	Input level, RF pins		5	dBm
T _{stg}	Storage temperature	-40	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values are with respect to ground, unless otherwise noted.
- (3) Including analog capable DIOs.

7.2 ESD Ratings

				VALUE	UNIT		
QFN packa	QFN packages						
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins	±2000	V		
V _{ESD} Electrostatic discharge	Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	All pins	±500	V			
WCSP pac	kages						
V	Electrostatio discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins	TBD	V		
V _{ESD} Electrostatic discharge	Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	All pins	TBD	V			

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
CC2240wwEwwww.dovieco.(125 °C. porto)	Operating ambient temperature ^{(1) (2)}	-40	125	°C
	Operating junction temperature ^{(1) (2)}	-40	125	°C
CC2240, and having devices (05 °C meth)	Operating ambient temperature ^{(1) (2)}	-40	85	°C
	Operating junction temperature ^{(1) (2)}	-40	85	°C
Operating supply voltage (VDDS)		1.71	3.8	V
Rising supply voltage slew rate		0	100	mV/µs
Falling supply voltage slew rate ⁽³⁾		0	1	mV/µs

(1) Operation at or near maximum operating temperature for extended durations will result in a reduction in lifetime.

(2) For thermal resistance details, refer to Thermal Resistance Characteristics table in this document.

(3) For small coin-cell batteries, with high worst-case end-of-life equivalent source resistance, a 10-µF VDDS input capacitor must be used to ensure compliance with this slew rate.

7.4 DCDC

When measured on the TTC2340R5 reference design with T_c = 25 °C and DCDC enabled unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VDDS supply voltage for DCDC operation ^{(1) (2)}		2.2	3.0	3.8	V

(1) When the supply voltage drops below the DCDC operation min voltage, the device automatically transitions to use GLDO regulator on-chip.

(2) A 10uH and 10uF load capacitor are required on the VDDR voltage rail. They should be placed close to the DCDC output pin.



^ङ TTC2340R52 SimpleLink™ Family of 2.4GHz Wireless MCUs

7.5 Global LDO (GLDO)

When measured on the TTC2340R5 reference design with $T_c = 25$ °C.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VDDS supply voltage for GLDO operation ⁽¹⁾		1.71	3.0	3.8	V

(1) A 10 µF capacitor is recommended at VDDR pin.

7.6 Power Supply and Modules

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
VDDS_BOD							
Brownout rising threshold ⁽¹⁾			1.68		V		
Brownout falling threshold ⁽¹⁾			1.67		V		
POR							
power-on reset power-up level			1.5		V		
power-on reset power-down level			1.45		V		

(1) Brown-out Detector is trimmed at initial boot, value is kept until device is reset by a POR reset or the RSTN pin.

7.7 Battery Monitor

Measured on the TTC2340R5 reference design with T_c = 25 °C, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			22		mV
Range		1.7		3.8	V
Accuracy	VDDS = 3.0 V		30		mV

7.8 Temperature Sensor

Measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
CC2340xxxExxxxx devices (125 °C devices)							
Accuracy	-40 °C to 125 °C	-15/+9 ⁽¹⁾		°C			
CC2340xxxNxxxxx devices (85 °C devices)							
Accuracy	-40 °C to 85 °C		±10 ⁽¹⁾		°C		

(1) Raw output from register.



7.9 Power Consumption - Power Modes

When measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, DCDC enabled, GLDO disabled, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN TYP MA		UNIT
Core Cu	rrent Consumpt	ion with DCDC	-		
I _{core}	Active	MCU running CoreMark from Flash at 48 MHz	2.6		mA
I _{core}	Active	MCU running CoreMark from Flash at 48MHz	53		µA / MHz
I _{core}	ldle	Supply Systems and RAM powered, flash disabled, DMA disabled	0.8		mA
I _{core}	Idle	Supply Systems and RAM powered, flash disabled, DMA enabled	0.8		mA
I _{core}	ldle	Supply Systems and RAM powered, flash enabled, DMA disabled	1.1		mA
I _{core}	Idle	Supply Systems and RAM powered, flash enabled, DMA enabled	1.2		mA
I _{core}	Standby	RTC running, full RAM retention LFOSC, DCDC recharge current setting (ipeak = 1)	0.71		μA
I _{core}	Standby	RTC running, full RAM retention LFXT, DCDC recharge current setting (ipeak = 1)	0.74		μA
Core Cu	rrent consumpt	ion with GLDO		I	
I _{core}	Active	MCU running CoreMark from Flash at 48 MHz	4.1		mA
I _{core}	Idle	Supply Systems and RAM powered, flash disabled, DMA disabled	1.2		mA
I _{core}	Idle	Supply Systems and RAM powered, flash disabled, DMA enabled	1.3		mA
I _{core}	ldle	Supply Systems and RAM powered, flash enabled, DMA disabled	1.5		mA
I _{core}	Idle	Supply Systems and RAM powered, flash enabled, DMA enabled	1.7		mA
I _{core}	Standby	RTC running, full RAM retention LFOSC, default GLDO recharge current setting	1.1		μA
I _{core}	Standby	RTC running, full RAM retention LFXT default GLDO recharge current setting	1.15		μA
Reset, S	hutdown Currer	nt Consumption			
I _{core}	Reset	Reset. RSTN pin asserted or VDDS below power-on-reset threshold	165		nA
I _{core}	Shutdown	Shutdown measured in steady state. No clocks running, no retention, IO wakeup enabled	165		nA
Peripher	al Current Cons	sumption			
I _{peri}	RF	Delta current, clock enabled, RF subsystem idle	40		μA
I _{peri}	Timers	Delta current with clock enabled, module is idle, one LGPT timer	2.4		μA
I _{peri}	I2C	Delta current with clock enabled, module is idle	10.6		μA
I _{peri}	SPI	Delta current with clock enabled, module is idle	3.4		μA
I _{peri}	UART	Delta current with clock enabled, module is idle	24.5		μA
I _{peri}	CRYPTO (AES)	Delta current with clock enabled, module is idle	3.8		μA



7.10 Power Consumption - Radio Modes

When measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V with DCDC enabled unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN TY	P MAX	UNIT
I _{RX}	Radio receive current	2440 MHz, 1 Mbps, GFSK, system bus off ⁽¹⁾	5	.3	mA
I _{RX}	Radio receive current	2440 MHz, 1 Mbps, GFSK, DCDC OFF, system bus off ⁽¹⁾		9	mA
I _{TX}	Radio transmit current	-8 dBm output power setting 2440 MHz system bus off ⁽¹⁾	4	.5	mA
I _{TX}	Radio transmit current	0 dBm output power setting 2440 MHz system bus off ⁽¹⁾	5	.1	mA
I _{TX}	Radio transmit current	0 dBm output power setting 2440 MHz DCDC OFF, system bus off ⁽¹⁾	9	.0	mA
I _{TX}	Radio transmit current	+4 dBm output power setting 2440 MHz system bus off ⁽¹⁾	7	.9	mA
I _{TX}	Radio transmit current	+6 dBm output power setting 2440 MHz system bus off ⁽¹⁾	8	.9	mA
I _{TX}	Radio transmit current	+8 dBm output power setting 2440 MHz system bus off ⁽¹⁾	10	.7	mA
I _{TX}	Radio transmit current	+8 dBm output power setting 2440 MHz DCDC OFF, system bus off ⁽¹⁾	1	19	mA

(1) System bus off refers to device idle mode, DMA disabled, flash disabled

7.11 Nonvolatile (Flash) Memory Characteristics

Over operating free-air temperature range and V_{DDS} = 3.0 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Flash sector size			2		KB
Supported flash erase cycles before failure, full bank ^{(1) (2)}		30			k Cycles
Supported flash erase cycles before failure, single sector ⁽³⁾		60			k Cycles
Maximum number of write operations per row before sector $\ensuremath{erase}^{(4)}$				83	Write Operations
CC2340xxxExxxxx devices (125 °C devices)					
Flash retention	105 °C	11.4			Years
Flash retention	125 °C	10			Years
CC2340xxxNxxxxx devices (85°C devices)					
Flash retention	85 °C	11.4			Years
Flash sector erase current	Average delta current		1.2		mA
Flash sector erase time ⁽⁵⁾	0 erase cycles		2.2		ms
Flash write current	Average delta current, full sector at a time		1.7		mA
Flash write time ⁽⁵⁾	full sector (2kB) at a time, 0 erase cycles		8.3		ms

(1) A full bank erase is counted as a single erase cycle on each sector

(2) Aborting flash during erase or program modes is not a safe operation.

(3) Up to 16 customer-designated sectors can be individually erased an additional 30k times beyond the baseline bank limitation of 30k cycles

(4) Each wordline is 2048 bits (or 256 bytes) wide. This limitation corresponds to sequential memory writes of 4 (3.1) bytes minimum per write over a whole wordline. If additional writes to the same wordline are required, a sector erase is required once the maximum number of write operations per row is reached.

(5) This number is dependent on Flash aging and increases over time and erase cycles

7.12 Thermal Resistance Characteristics

		PACKAGE			
THERMAL METRIC	THERMAL METRIC	RKP (VQFN)	RGE (VQFN)	UNIT ⁽¹⁾	
		40 PINS	24 PINS		
R _{eJA}	Junction-to-ambient thermal resistance	31.8	40.1	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	23.1	30.5	°C/W	
R _{eJB}	Junction-to-board thermal resistance	12.7	17.2	°C/W	

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7.12 Thermal Resistance Characteristics (continued)

		PACKAGE			
THERMAL METRIC	THERMAL METRIC	RKP (VQFN)	RGE (VQFN)		
		40 PINS	24 PINS		
Ψ _{JT}	Junction-to-top characterization parameter	0.3	0.4	°C/W	
Ψ _{JB}	Junction-to-board characterization parameter	12.7	17.1	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	3.3	3.4	°C/W	

(1) °C/W = degrees Celsius per watt.

7.13 RF Frequency Bands

Over operating free-air temperature range (unless otherwise noted).

PARAMETER	MIN	TYP MAX	
Frequency bands	2360	251	0 MHz



7.14 Bluetooth Low Energy - Receive (RX)

When measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
125 kbps (LE Coded)				
Receiver sensitivity	BER = 10 ⁻³	-102		dBm
Receiver saturation	BER = 10 ⁻³	5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-250/ 250) ⁽¹⁾		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-90 / 90) ⁽¹⁾		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)	> (-90 / 90) ⁽¹⁾		ppm
Co-channel rejection ⁽²⁾	Wanted signal at –79 dBm, modulated interferer in channel, BER = 10^{-3}	-6		dB
Selectivity, ±1 MHz ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	9 / 5 ⁽³⁾		dB
Selectivity, ±2 MHz ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at ±2 MHz, BER = 10^{-3}	44 / 31 ⁽³⁾		dB
Selectivity, ±3 MHz ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at ±3 MHz, BER = 10^{-3}	47 / 42 ⁽³⁾		dB
Selectivity, ±4 MHz ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	49 / 45 ⁽³⁾		dB
Selectivity, ±6 MHz ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at $\geq \pm 6$ MHz, BER = 10^{-3}	52 / 48 ⁽³⁾		dB
Selectivity, ±7 MHz	Wanted signal at –79 dBm, modulated interferer at $\geq \pm 7$ MHz, BER = 10^{-3}	54 / 49 ⁽³⁾		dB
Selectivity, Image frequency ⁽²⁾	Wanted signal at –79 dBm, modulated interferer at image frequency, BER = 10^{-3}	31		dB
Selectivity, Image frequency ±1 MHz ⁽²⁾	Note that Image frequency + 1 MHz is the Co- channel -1 MHz. Wanted signal at -79 dBm, modulated interferer at ±1 MHz from image frequency, BER = 10^{-3}	5 / 42 (3)		dB
500 kbps (LE Coded)				
Receiver sensitivity	BER = 10 ⁻³	_99		dBm
Receiver saturation	BER = 10 ⁻³	5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-250 / 250) ⁽¹⁾		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-90/ 90) ⁽¹⁾		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)	> (-90 / 90) ⁽¹⁾		ppm
Co-channel rejection ⁽²⁾	Wanted signal at –72 dBm, modulated interferer in channel, BER = 10^{-3}	-4.5		dB
Selectivity, ±1 MHz ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	9 / 5 (3)		dB
Selectivity, ±2 MHz ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at ±2 MHz, BER = 10^{-3}	42 / 31 ⁽³⁾		dB
Selectivity, ±3 MHz ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at ±3 MHz, BER = 10^{-3}	45 / 41 ⁽³⁾		dB
Selectivity, ±4 MHz ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	46 / 42 ⁽³⁾		dB
Selectivity, ±6 MHz ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at $\geq \pm 6$ MHz, BER = 10^{-3}	50 / 45 ⁽³⁾		dB
Selectivity, ±7 MHz	Wanted signal at –72 dBm, modulated interferer at $\geq \pm 7$ MHz, BER = 10^{-3}	51 / 46 ⁽³⁾		dB
Selectivity, Image frequency ⁽²⁾	Wanted signal at –72 dBm, modulated interferer at image frequency, BER = 10^{-3}	31		dB



7.14 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Selectivity, Image frequency ±1 MHz ⁽²⁾	Note that Image frequency + 1 MHz is the Co- channel -1 MHz. Wanted signal at -72 dBm, modulated interferer at ±1 MHz from image frequency, BER = 10^{-3}	5 / 41 ⁽³⁾		dB
1 Mbps (LE 1M)				
Receiver sensitivity	BER = 10 ⁻³	-96.5		dBm
Receiver saturation	BER = 10 ⁻³	5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-250/250) ⁽¹⁾		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-90 / 90) ⁽¹⁾		ppm
Co-channel rejection ⁽²⁾	Wanted signal at –67 dBm, modulated interferer in channel, BER = 10^{-3}	-6		dB
Selectivity, ±1 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	7 / 5 (3)		dB
Selectivity, ±2 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ±2 MHz,BER = 10^{-3}	39 / 28 ⁽³⁾		dB
Selectivity, ±3 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ± 3 MHz, BER = 10^{-3}	38 / 38 ⁽³⁾		dB
Selectivity, ±4 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	47 / 35 ⁽³⁾		dB
Selectivity, ±5 MHz or more ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at \geq ±5 MHz, BER = 10^{-3}	40		dB
Selectivity, image frequency ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at image frequency, BER = 10^{-3}	28		dB
Selectivity, image frequency ±1 MHz ⁽²⁾	Note that Image frequency + 1 MHz is the Co- channel -1 MHz. Wanted signal at -67 dBm, modulated interferer at \pm 1 MHz from image frequency, BER = 10 ⁻³	5 / 38 ⁽³⁾		dB
Out-of-band blocking ⁽⁴⁾	30 MHz to 2000 MHz	-10		dBm
Out-of-band blocking	2003 MHz to 2399 MHz	–10		dBm
Out-of-band blocking	2484 MHz to 2997 MHz	–10		dBm
Out-of-band blocking	3000 MHz to 12.75 GHz (excluding VCO frequency)	-2		dBm
Intermodulation	Wanted signal at 2402 MHz, -64 dBm. Two interferers at 2405 and 2408 MHz respectively, at the given power level	-37		dBm
Spurious emissions, 30 to 1000 MHz ⁽⁵⁾	Measurement in a 50- Ω single-ended load.	< -59		dBm
Spurious emissions, 1 to 12.75 GHz ⁽⁵⁾	Measurement in a 50- Ω single-ended load.	< -47		dBm
RSSI dynamic range (6)		70		dB
RSSI accuracy		±4		dB
RSSI resolution		1		dB
2 Mbps (LE 2M)				
Receiver sensitivity	Measured at SMA connector, BER = 10 ⁻³	-92		dBm
Receiver saturation	Measured at SMA connector, BER = 10 ⁻³	2		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-250 / 250) ⁽¹⁾		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-90/ 90) ⁽¹⁾		ppm
Co-channel rejection ⁽²⁾	Wanted signal at –67 dBm, modulated interferer in channel,BER = 10^{-3}	-8		dB
Selectivity, ±2 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ± 2 MHz, Image frequency is at –2 MHz, BER = 10^{-3}	9 / 5 (3)		dB
Selectivity, ±4 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	40 / 32 ⁽³⁾		dB

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7.14 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Selectivity, ±6 MHz ⁽²⁾	Wanted signal at –67 dBm, modulated interferer at ± 6 MHz, BER = 10^{-3}	46 / 40 ⁽³⁾		dB
Selectivity, image frequency ⁽²⁾	Wanted signal at -67 dBm, modulated interferer at image frequency, BER = 10^{-3}	5		dB
Selectivity, image frequency ±2 MHz ⁽²⁾	Note that Image frequency + 2 MHz is the Co-channel. Wanted signal at -67 dBm, modulated interferer at ± 2 MHz from image frequency, BER = 10^{-3}	8 / 32 ⁽³⁾		dB
Out-of-band blocking ⁽⁴⁾	30 MHz to 2000 MHz	-10		dBm
Out-of-band blocking	2003 MHz to 2399 MHz	-10		dBm
Out-of-band blocking	2484 MHz to 2997 MHz	–12		dBm
Out-of-band blocking	3000 MHz to 12.75 GHz (excluding VCO frequency)	-10		dBm
Intermodulation	Wanted signal at 2402 MHz, –64 dBm. Two interferers at 2408 and 2414 MHz respectively, at the given power level	-38		dBm

(1) Actual performance exceeding Bluetooth specification

(2) Numbers given as I/C dB

(3) X / Y, where X is +N MHz and Y is –N MHz

(4) Excluding one exception at F_{wanted} / 2, per Bluetooth Specification

(5) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan)

(6) The device will saturate at -30dB.



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7.15 Bluetooth Low Energy - Transmit (TX)

When measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
General Parameters						
Max output power	Delivered to a single-ended 50- Ω load through integrated balun		8		dBm	
Output power programmable range	Delivered to a single-ended 50- Ω load through integrated balun		28		dB	



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7.16 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - RX

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, f_{RF} = 2440 MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
General Parameters			·
Receiver sensitivity	PER = 1%	-98	dBm
Receiver saturation	PER = 1%	> 3	dBm
Adjacent channel rejection	Wanted signal at –82 dBm, modulated interferer at \pm 5 MHz, PER = 1%	36	dB
Alternate channel rejection	Wanted signal at –82 dBm, modulated interferer at ±10 MHz, PER = 1%	55	dB
Channel rejection, ±15 MHz or more	Wanted signal at –82 dBm, undesired signal is IEEE 802.15.4 modulated channel, stepped through all channels 2405 to 2480 MHz, PER = 1%	59	dB
Blocking and desensitization, 5 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	57	dB
Blocking and desensitization, 10 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	63	dB
Blocking and desensitization, 20 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	63	dB
Blocking and desensitization, 50 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	66	dB
Blocking and desensitization, –5 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	60	dB
Blocking and desensitization, –10 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	60	dB
Blocking and desensitization, –20 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	63	dB
Blocking and desensitization, –50 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	65	dB
Spurious emissions, 30 MHz to 1000 MHz	Measurement in a 50- Ω single-ended load ⁽¹⁾	-64	dBm
Spurious emissions, 1 GHz to 12.75 GHz	Measurement in a 50- Ω single-ended load ⁽¹⁾	-49	dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> 80	ppm
Symbol rate error tolerance	Difference between incoming symbol rate and the internally generated symbol rate	> 80	ppm
RSSI dynamic range		90	dB
RSSI accuracy		±4	dB

(1) Suitable for systems targeting compliance with EN 300 328, EN 300 440 class 2 (Europe), FCC CFR47, Part 15 (US) and ARIB STD-T-66 (Japan)



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7.17 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - TX

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, f_{RF} = 2440 MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
General Parameters							
Max output power (1)	Delivered to a single-ended 50- Ω load through integrated balun		8		dBm		
Output power programmable range	Delivered to a single-ended 50- Ω load through integrated balun		29		dB		
IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps)							
Error vector magnitude	+8 dBm setting		2		%		

(1) To ensure margins for passing FCC band edge requirements at 2483.5 MHz, a lower than maximum output-power setting or less than 100% duty cycle may be used when operating at the upper 802.15.4 channel(s).



7.18 Proprietary Radio Modes

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, f_{RF} = 2440 MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER TEST CONDITIONS		MIN	TYP I	MAX	UNIT		
2 Mbps GFSK (HID), 320 kHz deviation							
Receiver sensitivity	PER = 30.8%, Payload 37 bytes		-89		dBm		



7.19 2.4 GHz RX/TX CW

When measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DCDC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT
Spurious emissions a	nd harmonics				
	f < 1 GHz, outside restricted bands		< -36		dBm
	f < 1 GHz, restricted bands ETSI	<-54			dBm
Spurious emissions ⁽¹⁾	f < 1 GHz, restricted bands FCC	+8 dBm setting	<55		dBm
	f > 1 GHz, including harmonics (ETSI)		< -30		dBm
Harmonics (1)	Second harmonic				dBm
	Third harmonic		< -42		dBm

(1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).

7.20 Timing and Switching Characteristics

7.20.1 Reset Timing

PARAMETER	MIN	TYP MA	(UNIT
RSTN low duration	1		μs

7.20.2 Wakeup Timing

Measured over operating free-air temperature with V_{DDS} = 3.0 V (unless otherwise noted). The times listed here do not include any software overhead (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
MCU, Reset/Shutdown to Active ⁽¹⁾	GLDO default charge current setting, VDDR capacitor fully charged ⁽²⁾	350-450		μs
MCU, Standby to Active	MCU, Standby to Active (ready to execute code from flash). DCDC ON, default recharge current configuration	33-43 ⁽³⁾		μs
MCU, Standby to Active	MCU, Standby to Active (ready to execute code from flash). GLDO ON, default recharge current configuration	33-50 ⁽³⁾		μs
MCU, Idle to Active	Flash enabled in idle mode	3		μs
MCU, Idle to Active	Flash disabled in idle mode	14		μs

(1) Wakeup time includes device ROM bootcode execution time. The wakeup time is dependent on remaining charge on VDDR capacitor when starting the device, and thus how long the device has been in Reset or Shutdown before starting up again.

- (2) This is the best case reset/shutdown to active time (including ROM bootcode operation), for the specified GLDO charge current setting considering the VDDR capacitor is fully charged and is not discharged during the reset and shutdown events; that is, when the device is in reset / shutdown modes for only a very short period of time
- (3) Depending on VDDR capacitor voltage level.

7.20.3 Clock Specifications

7.20.3.1 48 MHz Crystal Oscillator (HFXT)

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.⁽⁴⁾

	PARAMETER	MIN	TYP M	IAX	UNIT
	Crystal frequency		48		MHz
ESR	Equivalent series resistance 6 pF < $C_L \leq 9 pF$		20	60	Ω
ESR	Equivalent series resistance 5 pF < $C_L \leq 6 pF$			80	Ω
CL	Crystal load capacitance ⁽¹⁾	5	7 ⁽²⁾	9	pF



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7.20.3.1 48 MHz Crystal Oscillator (HFXT) (continued)

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.⁽⁴⁾

	PARAMETER	MIN	TYP MAX	UNIT
Start-up time ⁽³⁾	Until clock is qualified		200	μs

(1) Adjustable load capacitance is integrated into the device. External load capacitors are required for systems targeting compliance with certain regulations.

(2) On-chip default connected capacitance including reference design parasitic capacitance. Connected internal capacitance is changed through software in the SysConfig.

- (3) Start-up time using the TI-provided power driver. Start-up time may increase if driver is not used.
- (4) Tai-Saw TZ3908AAAO43 has been validated for TTC2340R5 design.

7.20.3.2 48 MHz RC Oscillator (HFOSC)

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Frequency		48		MHz
Uncalibrated frequency accuracy		±3		%
Calibrated frequency accuracy (1)		±0.25		%

(1) Accuracy relative to the calibration source (HFXT)

7.20.3.3 32 kHz Crystal Oscillator (LFXT)

Measured on the TTC2340R5 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Crystal frequency		32.768		kHz
Supported crystal load capacitance	6		12	pF
ESR		30	100	kΩ

7.20.3.4 32 kHz RC Oscillator (LFOSC)

Measured on the TTC2340R5 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency	32.768 ⁽¹⁾		kHz	

(1) When using LFOSC as source for the low frequency system clock (LFCLK), the accuracy of the LFCLK-derived Real Time Clock (RTC) can be improved by measuring LFOSC relative to HFXT and compensating for the RTC tick speed. This functionality is available through the TI-provided Power driver.

7.21 Peripheral Characteristics

7.21.1 UART

7.21.1.1 UART Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	MIN	TYP	MAX	UNIT
UART rate			3	MBaud

7.21.2 SPI

7.21.2.1 SPI Characteristics

Using TI SPI driver, over operating free-air temperature range (unless otherwise noted).

PARAMETERS		TEST CONDITIONS	MIN	TYP	MAX	UNIT
fSCLK 1/tsclk	SPI clock frequency	Controller Mode and Peripheral Mode $^{(1)}$ 2.7V \leq VDDS $<$ 3.8V			12	MHz
	SPT Clock nequency	Controller Mode and Peripheral Mode ⁽¹⁾ VDDS < 2.7V			8	MHz
DC _{SCK}	SCK Duty Cycle		45	50	55	%

(1) Assume interfacing with ideal SPI controller and SPI peripheral devices



7.21.2.2 SPI Controller Mode

Using TI SPI driver, over operating free-air temperature range (unless otherwise noted)

	PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{SCLK_H} / L	SCLK High or Low time		(t _{SPI} /2) - 1	t _{SPI} /2 ^{(t_{SF}}	⊳ı/2) + 1	ns
t _{CS.LEAD}	CS lead-time, CS active to clock		1			SCLK
t _{CS.LAG}	CS lag time, Last clock to CS inactive		1			SCLK
t _{CS.ACC}	CS access time, CS active to PICO data out				1	SCLK
t _{CS.DIS}	CS disable time, CS inactive to PICO high impedance				1	SCLK
t _{VALID.C} O	PICO output data valid time ⁽¹⁾	SCLK edge to PICO valid,C∟ = 20 pF			13	ns
t _{HD.CO}	PICO output data hold time ⁽²⁾	C _L = 20 pF	0			ns

Specifies the time to drive the next valid data to the output after the output changing SCLK clock edge Specifies how long data on the output is valid after the output changing SCLK clock edge (1)

(2)

7.21.2.3 SPI Timing Diagrams - Controller Mode

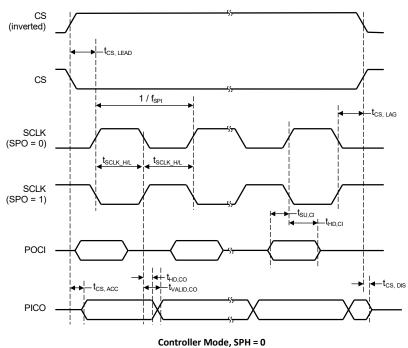
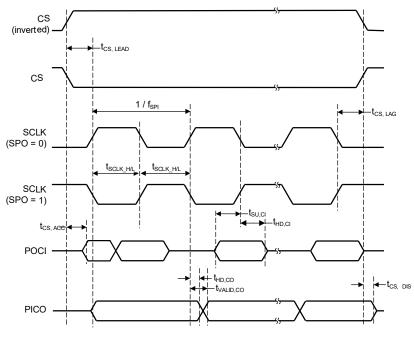


Figure 7-1. SPI Timing Diagram - Controller Mode, SPH = 0



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Controller Mode, SPH = 1

Figure 7-2. SPI Timing Diagram - Controller Mode, SPH = 1

7.21.2.4 SPI Peripheral Mode

Using TI SPI driver, over operating free-air temperature range (unless otherwise noted)

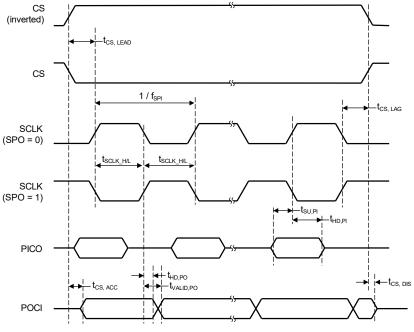
	PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{CS.LEAD}	CS lead-time, CS active to clock		1			SCLK
t _{CS.LAG}	CS lag time, Last clock to CS inactive		1			SCLK
t _{CS.ACC}	CS access time, CS active to POCI data out	VDDS = 3.3V			35	ns
t _{CS.ACC}	CS access time, CS active to POCI data out	VDDS = 1.8V			50	ns
t _{CS.DIS}	CS disable time, CS inactive to POCI high impedance	VDDS = 3.3V			35	ns
t _{CS.DIS}	CS disable time, CS inactive to POCI high impedance	VDDS = 1.8V			50	ns
t _{SU.PI}	PICO input data setup time		13			ns
t _{HD.PI}	PICO input data hold time		0			ns
t _{VALID.P} O	POCI output data valid time ⁽¹⁾	SCLK edge to POCI valid,C∟ = 20pF, 3.3V			35	ns
t _{VALID.P} O	POCI output data valid time ⁽¹⁾	SCLK edge to POCI valid,C∟ = 20pF, 1.8V			50	ns
t _{HD.PO}	POCI output data hold time ⁽²⁾	C _L = 20pF	0			ns

(1) Specifies the time to drive the next valid data to the output after the output changing SCLK clock edge

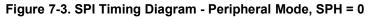
(2) Specifies how long data on the output is valid after the output changing SCLK clock edge



7.21.2.5 SPI Timing Diagrams - Peripheral Mode



Peripheral Mode, SPH = 0



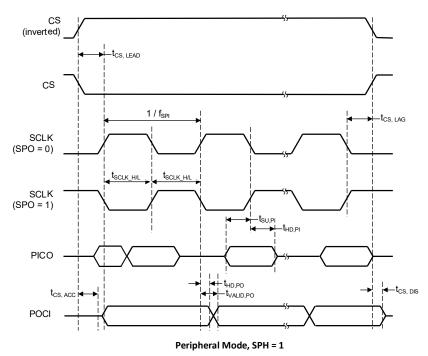


Figure 7-4. SPI Timing Diagram - Peripheral Mode, SPH = 1



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7.21.3 I²C

7.21.3.1 I2C

Over operating free-air temperature range (unless otherwise noted)

	PARAMETERS	TEST CONDITIONS	MIN	TYP MAX	UNIT
f _{SCL}	SCL clock frequency		0	400	kHz
t _{HD,STA}	Hold time (repeated) START	f _{SCL} = 100kHz	4.0		μs
t _{HD,STA}	Hold time (repeated) START	f _{SCL} > 100kHz	0.6		μs
t _{SU,STA}	Setup time for a repeated START	f _{SCL} = 100kHz	4.7		μs
t _{SU,STA}	Setup time for a repeated START	f _{SCL} > 100kHz	0.6		μs
t _{HD,DAT}	Data hold time		0		μs
t _{SU,DAT}	Data setup time	f _{SCL} = 100kHz	250		ns
t _{SU,DAT}	Data setup time	f _{SCL} > 100kHz	100		ns
t _{SU,STO}	Setup time for STOP	f _{SCL} = 100kHz	4.0		μs
t _{SU,STO}	Setup time for STOP	f _{SCL} > 100kHz	0.6		μs
t _{BUF}	Bus free time between STOP and START conditions	f _{SCL} = 100kHz	4.7		μs
t _{BUF}	Bus free time between STOP and START conditions	f _{SCL} > 100kHz	1.3		μs
t _{SP}	Pulse duration of spikes suppressed by input deglitch filter		50		ns

7.21.3.2 I²C Timing Diagram

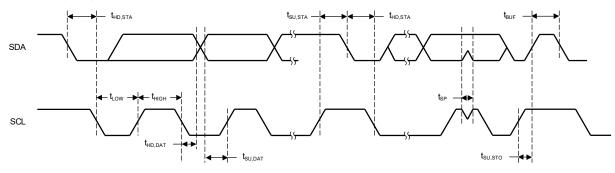


Figure 7-5. I²C Timing Diagram

7.21.4 GPIO

7.21.4.1 GPIO DC Characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
T _A = 25 °C, V _{DDS} = 1.8 V					
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V	39	66	109	μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDDS	10	21	40	μA
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as $0 \rightarrow 1$	0.91	1.11	1.27	V
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as $1 \rightarrow 0$	0.59	0.75	0.91	V
GPIO input hysteresis	IH = 1, difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.26	0.35	0.44	V
$T_A = 25 \ ^{\circ}C, \ V_{DDS} = 3.0 \ V$					
GPIO VOH at 10 mA load	high-drive GPIOs only, max drive setting	2.47			V
GPIO VOL at 10 mA load	high-drive GPIOs only, max drive setting			0.25	V
GPIO VOH at 2 mA load	standard drive GPIOs	2.52			V



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7.21.4.1 GPIO DC Characteristics (continued)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
GPIO VOL at 2 mA load	standard drive GPIOs			0.20	V
T _A = 25 °C, V _{DDS} = 3.8 V	•				
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V	170	262	393	μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDDS	60	110	172	μA
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as $0 \rightarrow 1$	1.76	1.98	2.27	V
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as $1 \rightarrow 0$	1.26	1.52	1.79	V
GPIO input hysteresis	IH = 1, difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.40	0.47	0.54	V
T _A = 25 °C					
VIH	Lowest GPIO input voltage reliably interpreted as a High	0.8*V _{DDS}			V
VIL	Highest GPIO input voltage reliably interpreted as a Low			0.2*V _{DDS}	V



7.21.5 ADC

7.21.5.1 Analog-to-Digital Converter (ADC) Characteristics

 $T_{\rm c}$ = 25°C, V_{DDS} = 3.0V, unless otherwise noted. $^{(2)}$

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
ADC Pov	ver Supply and Input Range C	onditions			
V _(Ax)	Analog input voltage range	All ADC analog input pins Ax	0	VDDS	V
l _(ADC) single-	Operating supply current	RES = 0x0 (12Bit mode), Fs = 1.2MSPS, Internal reference OFF (ADCREF_EN = 0), VeREF+ = VDDS	480		μA
ended mode	into VDDS terminal	RES = 0x0 (12Bit mode), Fs = 266ksps, Internal reference ON (ADCREF_EN = 0), ADCREF = 2.5V	365		μΛ
C _{I GPIO}	Input capacitance into a single terminal		5	7	pF
R _{I GPIO}	Input MUX ON-resistance		0.5	1	kΩ
ADC Swi	tching Characteristics				
F _s ADC REF	ADC sampling frequency when using the internal ADC reference voltage	ADCREF_EN = 1, RES = 0x0 (12-bit), VDDS = 1.71V to VDDSmax		267 (1)	ksps
Fs ADC REF	ADC sampling frequency when using the internal ADC reference voltage	ADCREF_EN = 1, RES = 0x1 (10-bit), VDDS = 1.71V to VDDSmax		308 (1)	ksps
Fs ADC REF	ADC sampling frequency when using the internal ADC reference voltage	ADCREF_EN = 1, RES = 0x2 (8-bit), VDDS = 1.71V to VDDSmax		400 (1)	ksps
Fs EXTR EF	ADC sampling frequency when using the external ADC reference voltage	ADCREF_EN = 0, VeREF+ = VDDS, RES = 0x0 (12-bit), VDDS = 1.71V to VDDSmax		1.2 (1)	Msps
F _s EXTR EF	ADC sampling frequency when using the external ADC reference voltage	ADCREF_EN = 0, VeREF+ = VDDS, RES = 0x1 (10-bit), VDDS = 1.71V to VDDSmax	1.33 ⁽¹⁾		Msps
Fs EXTR EF	ADC sampling frequency when using the external ADC reference voltage	ADCREF_EN = 0, VeREF+ = VDDS, RES = 0x2 (8-bit), VDDS = 1.71V to VDDSmax		1.6 ⁽¹⁾	Msps
N _{CONVER} T	Clock cycles for conversion	RES = 0x0 (12-bit)	14		cycles
N _{CONVER} T	Clock cycles for conversion	RES = 0x1 (10-bit)	12		cycles
N _{CONVER} T	Clock cycles for conversion	RES = 0x2 (8-bit)	9		cycles
t _{Sample}	Sampling time	RES = 0x0 (12-bit), R _S = 25 Ω , C _{pext} = 10 pF. +/- 0.5 LSB settling	250		ns
t _{VSUPPLY/} 3(sample)	Sample time required when Vsupply/3 channel is selected		20		μs
ADC Line	earity Parameters				
Eı	Integral linearity error (INL) for single-ended inputs	12-bit Mode, V _{R+} = VeREF+ = VDDS, VDDS=1.71>3.8	+/- 2		LSB
ED	Differential linearity error (DNL)	12-bit Mode, V _{R+} = VeREF+ = VDDS, VDDS=1.71>3.8	+/- 1		LSB
Eo	Offset error	12-bit Mode, External reference, V _{R+} = VeREF+ = VDDS, VDDS=1.71>3.8	1.98		LSB
Eo	Offset error	12-bit Mode, Internal reference, V_{R*} = ADCREF = 2.5V	1.02		LSB
Eg	Gain error	External Reference, V_{R+} = VeREF+ = VDDS , VDD= 1.71>3.8	+/- 2		LSB
Eg	Gain error	Internal reference, V_{R+} = ADCREF = 2.5V	+/- 40		LSB
ADC Dyn	amic Parameters				
ENOB	Effective number of bits	ADCREF_EN = 0, VeREF+ = VDDS =3.3V, VeREF-=0V, RES = 0x2 (8-bit)	8		bit
ENOB	Effective number of bits	ADCREF_EN = 0, VeREF+ = VDDS =3.3V, VeREF-=0V, RES = 0x1 (10-bit)	9.9		bit

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7.21.5.1 Analog-to-Digital Converter (ADC) Characteristics (continued)

 T_c = 25°C, V_{DDS} = 3.0V, unless otherwise noted.⁽²⁾

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT	
ENOB	Effective number of bits	ADCREF_EN = 0, VeREF+ = VDDS =3.3V, VeREF-=0V, RES = 0x0 (12-bit)	11.2	bit		
ENOB	Effective number of bits	ADCREF_EN = 1, ADCREF_VSEL = {2.5V, 1.4V}, RES = 0x2 (8-bit)	8	bit		
ENOB	Effective number of bits	ADCREF_EN = 1, ADCREF_VSEL = {2.5V, 1.4V} , RES = 0x1 (10-bit)	9.6		bit	
ENOB	Effective number of bits	ADCREF_EN = 1, ADCREF_VSEL = {2.5V, 1.4V}, RES = 0x0 (12-bit)	10.4		bit	
ENOB	Effective number of bits	VDDS reference, RES = 0x0 (12-bit)	11.2		bit	
SINAD	Signal-to-noise and distortion ratio	ADCREF_EN = 0, VeREF+ = VDDS =3.3V, VeREF-=0V, RES = 0x0 (12-bit)	69.18		dB	
SINAD	Signal-to-noise and distortion ratio	ADCREF_EN = 1, ADCREF_VSEL = {2.5V, 1.4V}, RES = 0x0 (12-bit)	64.37		dB	
SINAD	Signal-to-noise and distortion ratio	VDDS reference, RES = 0x0 (12-bit)	69.18		dB	
ADC Exte	ernal Reference					
EXTREF	Positive external reference voltage input	ADCREF_EN=0, ADC reference sourced from external reference pin (VeREF+)	1.4	VDDS	V	
EXTREF	Negative external reference voltage input	ADCREF_EN=0, ADC reference sourced from external reference pin (VeREF-)		0	V	
ADC Tem	perature Diode, Supply Monit	tor		I		
Temp_di ode Accurac y	Temperature Error	ADC input channel: Temp diode voltage, Error calculated in temperature range: -30C to +40C, with single point calibration ⁽²⁾	+/- 3		С	
ADC Internal Input: V _{SUPPLY} / 3 Accurac y	V _{supply} voltage divider accuracy for supply monitoring	ADC input channel: Vsupply monitor	+/- 1		%	
ADC Internal Input: I _{Vsupply/3}	V _{supply} voltage divider current consumption	ADC input channel Vsupply monitor. V _{supply} =VDDS=3.3V	10		μΑ	
ADC Inte	rnal and VDDS Reference					
VDDSR EF	Positive ADC reference voltage	ADC reference sourced from VDDS	VDDS		V	
ADCRE	Internal ADC Reference	ADCREF_EN = 1, ADCREF_VSEL = 0, VDDS = 1.71V - VDDSmax	1.4		V	
F	Voltage	ADCREF_EN = 1, ADCREF_VSEL = 1, VDDS = 2.7V - VDDSmax	2.5	V		
IADCREF	Operating supply current into VDDA terminal with internal reference ON	ADCREF_EN = 1, VDDA = 1.7V to VDDAmax, ADCREF_VSEL = {0,1}	80		μA	
t _{on}	Internal ADC Reference Voltage power on-time	ADCREF_EN = 1	2		μs	

(1) Measured with 48MHz HFOSC

(2) Using IEEE Std 1241-2010 for terminology and test methods



7.21.6 Comparators

7.21.6.1 Ultra-Low Power Comparator

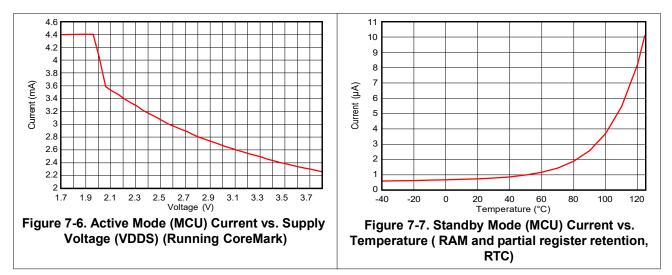
 $T_c = 25^{\circ}C$, $V_{DDS} = 3.0V$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range		0		V_{DDS}	V
Clock frequency			32		KHz
Voltage Divider Accuracy	Input voltage range is between VDDS/4 and VDDS.		98%		
Offset	Measured at V_{DDS} / 2 (Errors seen when using two external inputs)		±27.3		mV
Decision time	Step from –50mV to 50mV		1	3	Clock Cycle
Comparator enable time	COMP_LP disable → enable, VIN+, VIN- from pins, Overdrive ≥ 20mV		70		μs
Current consumption	Including using VDDS/2 as internal reference at VIN– comparator terminal		370		nA

7.22 Typical Characteristics

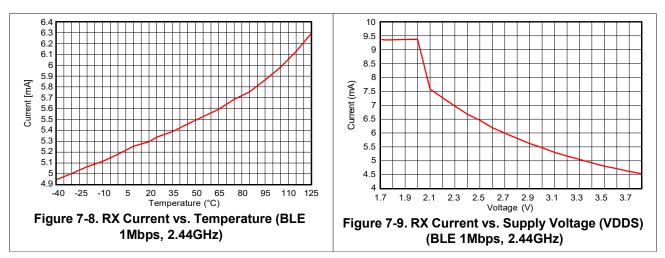
All measurements in this section are done with $T_c = 25^{\circ}C$ and $V_{DDS} = 3.0V$, unless otherwise noted. See *Recommended Operating Conditions* for device limits. Values exceeding these limits are for reference only.

7.22.1 MCU Current





7.22.2 RX Current





7.22.3 TX Current

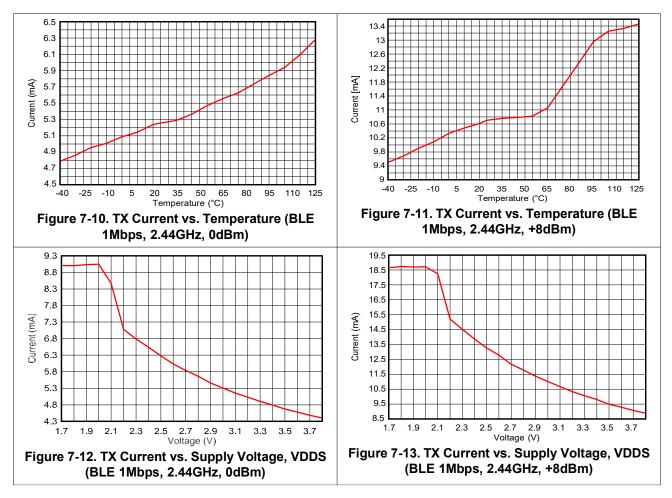




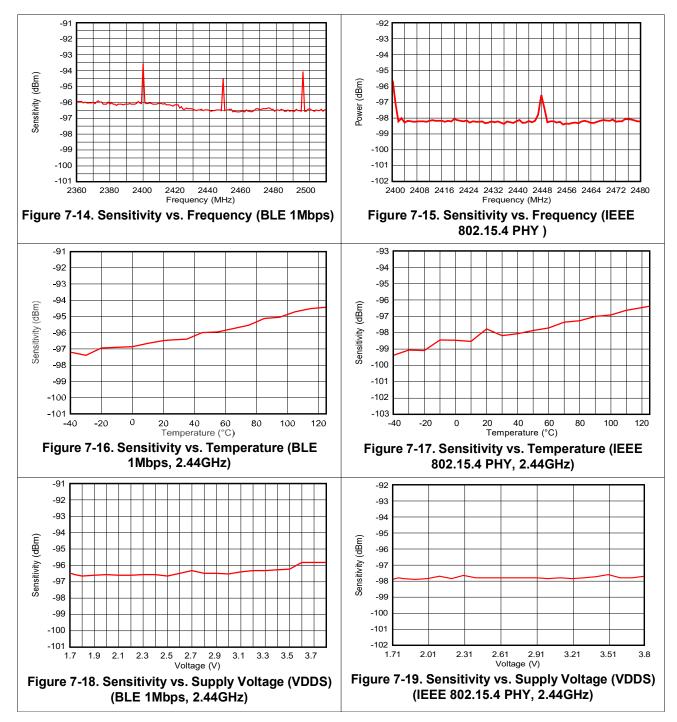
Table 7-1 shows typical TX current and output power for different output power settings.

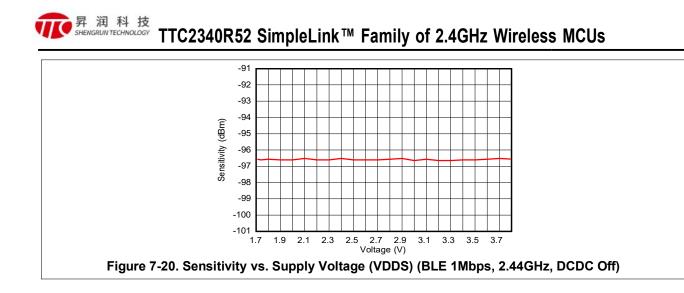
	2.4 GHz, VDDS = 3.0 V, DCDC=On,	Temperature = 25 °C (Measured on	LP-EM-TTC2340R5)
txPowerTable Index	TX Power Setting [dBm] (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]
13	8	7.7	10.7
12	7	7.1	9.5
11	6	6.3	8.9
10	5	5.5	8.3
9	4	4.5	7.9
8	3	3.7	7.5
7	2	2.4	7.1
6	1	1.0	5.4
5	0	0.4	5.1
4	-4	-3.1	4.8
3	-8	-7.3	4.5
2	-12	-10.9	4.2
1	-16	-15.1	4.0
0	-20	-19.0	3.8

Table 7-1. Typical TX Current and Output Power



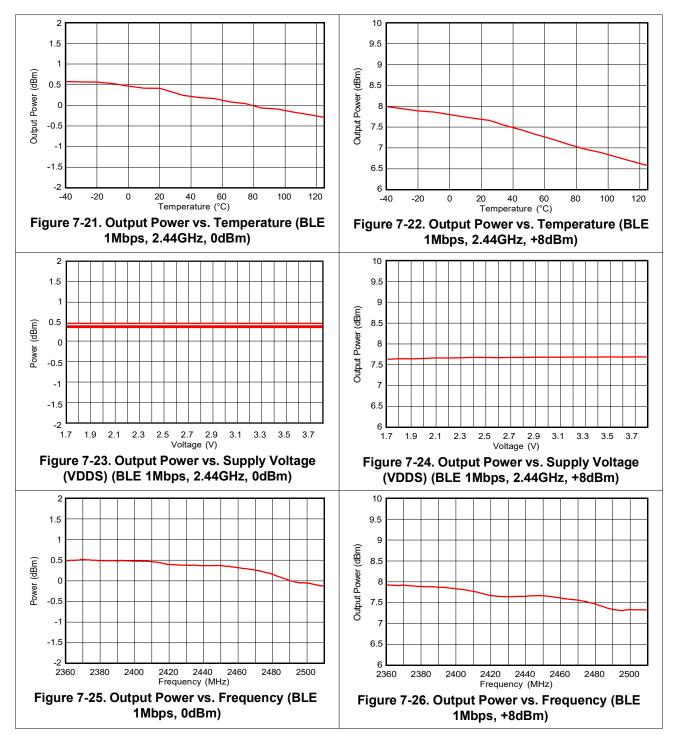
7.22.4 RX Performance







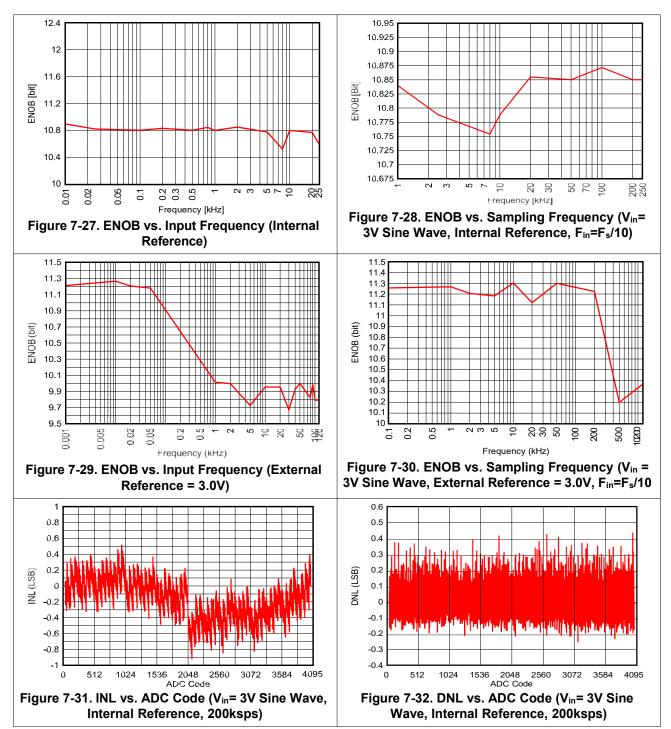
7.22.5 TX Performance

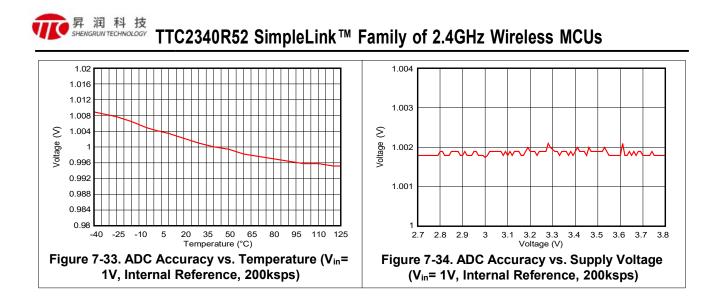


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7.22.6 ADC Performance







8 Detailed Description

8.1 Overview

Section 4 shows the core modules of the TTC2340R device.

8.2 System CPU

The TTC2340R SimpleLink[™] Wireless MCU contains an Arm[®] Cortex[®]-M0+ system CPU, which runs the application, the protocol stacks, and the radio. The Cortex-M0+ processor is built on a highly area and power optimized 32-bit processor core, with a 2-stage pipeline Von Neumann architecture. The processor delivers exceptional energy efficiency through a small but powerful instruction set and extensively optimized design, providing high-end processing hardware including a single-cycle multiplier. The Cortex-M0+ processor offers multiple benefits to developers including:

- Ultra-low power, energy efficient operation
- Deterministic, high-performance interrupt handling for time-critical applications
- Upward compatibility with the Cortex-M processors family

The Cortex-M0+ processor provides the excellent performance expected of a modern 32-bit architecture core, with higher code density than other 8-bit and 16-bit microcontrollers. Its features include the following:

- ARMv6-M architecture optimized for small-footprint embedded applications
- Subset of Arm Thumb/Thumb-2 mixed 16- and 32-bit instructions delivers the high performance expected of a 32-bit Arm
- Single-cycle multiply instruction
- VTOR supporting offset of the vector table base address
- Serial Wire debug with HW break-point comparators
- Ultra-low-power consumption with integrated sleep modes
- SysTick timer
- 48MHz operation
- 0.99DMIPS/MHz

Additionally, the TTC2340R devices are compatible with all ARM tools and software.

8.3 Radio (RF Core)

The low-power RF Core (LRF) implements a high performance and highly flexible RF sub system containing RF and baseband circuitry in addition to a software defined digital radio (LRFD). LRFD provides a high-level, command-based API to the main CPU and handles all of the timing critical and low-level details of many different radio PHYs. Several signals are also available to control external circuitry such as RF switches or range extenders autonomously.

The software-defined modem is not programmable by customers but is instead loaded with precompiled images provided in the radio driver in the SimpleLink[™] Low Power F3 software development kit (SDK) for the CC23xx devices. This mechanism allows the radio platform to be updated for support of future versions of standards with over-the-air (OTA) updates while still using the same silicon. LRFD stores the code images in the RF SRAM and does not make use of any ROM memory, thus image loading from NV memory only occurs once after boot and also, no patching is required when exiting power modes.

8.3.1 Bluetooth 5.3 Low Energy

The RF Core offers full support for Bluetooth 5.3 Low Energy, including the high-speed 2Mbps physical layer and the 500kbps and 125kbps long range PHYs (Coded PHY) through the TI provided Bluetooth 5.3 stack or through a high-level Bluetooth API.

The new high-speed mode allows data transfers up to 2Mbps, twice the speed of Bluetooth 4.2 and five times the speed of Bluetooth 4.0, without increasing power consumption. In addition to faster speeds, this mode offers significant improvements in energy efficiency and wireless coexistence with reduced radio communication time.



Bluetooth 5.3 also enables unparalleled flexibility for adjustment of speed and range based on application needs, which capitalizes on the high-speed or long-range modes respectively. Data transfers are now possible at 2Mbps, enabling the development of applications using voice, audio, imaging, and data logging that were not previously an option using Bluetooth low energy. With high-speed mode, existing applications deliver faster responses, richer engagement, and longer battery life. Bluetooth 5.3 enables fast, reliable firmware updates.

8.3.2 802.15.4 (Thread and Zigbee)

Through a dedicated IEEE radio API, the RF Core supports the 2.4GHz IEEE 802.15.4-2011 physical layer (2 Mchips per second Offset-QPSK with DSSS 1:8), used in Thread and Zigbee protocols. TI also provides royalty-free protocol stacks for Thread and Zigbee, enabling a robust end-to end solution.

8.4 Memory

Up to 512KB nonvolatile (Flash) memory provides storage for code and data. The flash memory is in-system programmable and erasable. A special flash memory sector must contain a Customer Configuration section (CCFG) that is used by boot ROM and TI provided drivers to configure the device. This configuration is done through the ccfg.c source file that is included in all TI provided examples.

Up to 64KB ultra-low leakage system static RAM (SRAM) can be used for both storage of data and execution of code. Retention of SRAM contents in Standby power mode is enabled by default and included in Standby mode power consumption numbers. System SRAM is always initialized to zeroes upon code execution during boot.

The ROM includes device bootcode firmware handling initial device trimming operations, security configurations, and device lifecycle management. The ROM also contains a serial (SPI and UART) bootloader that can be used for the initial programming of the device.



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8.5 Cryptography

The TTC2340R device comes with AES-128 cryptography hardware accelerator, reducing code footprint and execution time for cryptographic operations. It also has the benefit of being lower power and improves availability and responsiveness of the system because the cryptography operations run in a background hardware thread. The AES hardware accelerators supports the following block cipher modes and message authentication codes:

- AES ECB encrypt
- AES CBC encrypt
- AES CTR encrypt/decrypt
- AES CBC-MAC
- AES GCM
- AEC CCM (uses a combination of CTR + CBC-MAC hardware via software drivers)

The AES hardware accelerator can be fed with plaintext/ciphertext from either CPU or using DMA. Sustained throughput of one 16 byte ECB block per 23 cycles is possible corresponding to > 30Mbps.

The TTC2340R device supports Random Number Generation (RNG) using on-chip analog noise as the non-deterministic noise source for the purpose of generating a seed for a cryptographically secure counter deterministic random bit generator (CTR-DRBG) that in turn is used to generate random numbers for keys, initialization vectors (IVs), and other random number requirements. Hardware acceleration of AES CTR-DRBG is supported.

The TTC2340R device includes a complete SHA 256 library in ROM, reducing the code footprint of the application. Uses cases may include generating digests for use in digital signature algorithms, data integrity checks, and password storage.

Together with a large selection of open-source cryptography libraries provided with the Software Development Kit (SDK), this allows for secure and future proof IoT applications to be easily built on top of the platform.

8.6 Timers

A large selection of timers are available as part of the TTC2340R device. These timers are:

• Real-Time Clock (RTC)

The RTC is a 67-bit, 2-channel timer running on the LFCLK system clock. The RTC is active in STANDBY and ACTIVE power states. When the device enters the RESET or SHUTDOWN state the RTC is reset.

The RTC accumulates time elapsed since reset on each LFCLK. The RTC counter is incremented by LFINC at a rate of 32.768kHz. LFINC indicates the period of LFCLK in μ s, with an additional granularity of 16 fractional bits.

The counter can be read from two 32-bit registers. RTC.TIME8U has a range of approximately 9.5 hours with an LSB representing 8 microseconds. RTC.TIME524M has a range of approximately 71.4 years with an LSB representing 524 milliseconds.

There is hardware synchronization between the system timer (SYSTIM) and the RTC so that the multichannel and higher resolution SYSTIM remains in synchronization with the RTC's time base.

The RTC has two channels: one compare channel and one capture channel and is capable of waking the device out of the standby power state. The RTC compare channel is typically used only by system software and only during the standby power state.

• System Timer (SYSTIM)

The SYSTIM is a 34-bit, 5-channel wrap-around timer with a per-channel selectable 32b slice with either a 1µs resolution and 1h11m35s range or 250ns resolution and 17m54s range. All channels support both capture and single-shot compare (posting an event) operation. One channel is reserved for system software, three channels are reserved for radio software and one channel is freely available to user applications.

For software convenience, a hardware synchronization mechanism automatically ensures that the RTC and SYSTIM share a common time base (albeit with different resolutions/spans). Another software convenience



feature is that SYSTIM qualifies any submitted compare values so that the timer channel will immediately trigger if the submitted event is in the immediate past (4.294s with 1µs resolution and 1.049s with 250ns resolution).

• General Purpose Timers (LGPT)

The TTC2340R device provides up to four LGPTs with 3 × 16 bit timers and 1× 24 bit timer, all running up to 48MHz. The LGPTs support a wide range of features such as:

- Three capture/compare channels
- One-shot or periodic counting
- Pulse width modulation (PWM)
- Time counting between edges and edge counting
- Input filter implemented on each of the channels for all timers
- IR generation feature available on Timer-0 and Timer-1
- Dead band feature available on Timer-1

The timer capture/compare and PWM signals are connected to IOs through the IO controller module (IOC) and the internal timer event connections to CPU, DMA, and other peripherals are through the event fabric, which allows the timers to interact with signals such as GPIO inputs, other timers, DMA and ADC. Two LGPTs (2× 16-bit timers) support quadrature decoder mode to enable buffered decoding of quadrature-encoded sensor signals. The LGPTs are available in device Active and Idle power modes.

Feature	Timer 0	Timer 1	Timer 2	Timer 3
Counter Width	16-bit	16-bit	16-bit	24-bit
Quadrature Decoder	Yes	No	Yes	No
Park Mode on Fault	No	Yes	No	No
Programmable Dead- Band Insertion	No	Yes	No	No

Table 8-1. Timer Comparison

Table 8-2. Tir	ner Availability
----------------	------------------

Part Number	Timer 0	Timer 1	Timer 2	Timer 3
TTC2340R52	Yes	Yes	Yes	Yes

· Watchdog timer

The watchdog timer is used to regain control if the system operates incorrectly due to software errors. Upon counter expiry, the watchdog timer resets the device when periodic monitoring of the system components and tasks fails to verify proper functionality. The watchdog timer runs on a 32kHz clock rate and operates in device active, idle, and standby modes and cannot be stopped once enabled.

8.7 Serial Peripherals and I/O

The TTC2340R device provides 1xUART, 1xSPI, and 1xI2C serial peripherals.

The SPI module supports both SPI controller and peripheral up to 12MHz with configurable phase and polarity.

The UART module implements universal asynchronous receiver and transmitter functions. They support flexible baud-rate generation up to a maximum of 3Mbps and IRDA SIR mode of operation.

The I²C module is used to communicate with devices compatible with the I²C standard. The I²C interface can handle 100kHz and 400kHz operation and can serve as both controller and target.

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The I/O controller (IOC) controls the digital I/O pins and contains multiplexer circuitry to allow a set of peripherals to be assigned to I/O pins in a fixed manner over DIOs. All digital I/Os are interrupt and wake-up capable, have a programmable pullup and pulldown function, and can generate an interrupt on a negative or positive edge (configurable). When configured as an output, pins can function as either push-pull, open-drain, or open-source. Some GPIOs have high-drive capabilities, which are marked in **bold** in *Pin Configurations and Functions*.

For more information, see the CC23xx SimpleLink™ Wireless MCU Technical Reference Manual.

8.8 Battery and Temperature Monitor

A combined temperature and battery voltage monitor is available in the TTC2340R device. The battery and temperature monitor allows an application to continuously monitor on-chip temperature and supply voltage and respond to changes in environmental conditions as needed. The module contains window comparators to interrupt the system CPU when temperature or supply voltage go outside defined windows. These events can also be used to wake up the device from Standby mode through the Always-On (AON) event fabric.

8.9 µDMA

The device includes a direct memory access (μ DMA) controller. The μ DMA controller provides a way to offload data-transfer tasks from the system CPU, thus allowing for more efficient use of the processor and the available bus bandwidth. The μ DMA controller can perform a transfer between memory and peripherals. The μ DMA controller has dedicated channels for each supported on-chip module and can be programmed to automatically perform transfers between peripherals and memory when the peripheral is ready to transfer more data.

Some features of the µDMA controller include the following (this is not an exhaustive list):

- Channel operation of up to 8 channels, with 6 channels having dedicated peripheral interface and 2 channels having ability to be triggered via configurable events.
- Transfer modes: memory-to-memory, memory-to-peripheral, peripheral-to-memory, and peripheral-to-peripheral
- Data sizes of 8, 16, and 32 bits
- Ping-pong mode for continuous streaming of data

8.10 Debug

On-chip debug is supported through the serial wire debug (SWD) interface, which is an ARM bi-directional 2-wire protocol that communicates with the JTAG Test Access Port (TAP) controller and allows for complete debug functionality. SWD is fully compatible with Texas Instruments' XDS family of debug probes.



8.11 Power Management

To minimize power consumption, the TTC2340R supports a number of power modes and power management features (see Table 8-3).

SOFTWARE CONFIGURABLE POWER MODES (1)									
MODE	ACTIVE	IDLE	STANDBY	SHUTDOWN	RESET PIN HELD				
CPU	Active	Off	Off	Off	Off				
Flash	On	Available	Off	Off	Off				
SRAM	On	On	Retention	Off	Off				
Radio	Available	Available	Off	Off	Off				
Supply System	On	On	Duty Cycled	Off	Off				
CPU register retention	Full	Full	Full ⁽²⁾	No	No				
SRAM retention	Full	Full	Full	Off	Off				
48 MHz high-speed clock (HFCLK)	HFOSC (tracks HFXT)	HFOSC (tracks HFXT)	Off	Off	Off				
32 kHz low-speed clock (LFCLK)	LFXT or LFOSC	LFXT or LFOSC	LFXT or LFOSC	Off	Off				
Peripherals	Available	Available	IOC, BATMON, RTC, LPCOMP	Off	Off				
Wake-up on RTC	N/A	Available	Available	Off	Off				
Wake-up on pin edge	N/A	Available	Available	Available	Off				
Wake-up on reset pin	On	On	On	On	On				
Brownout detector (BOD)	On	On	Duty Cycled	Off	Off				
Power-on reset (POR)	On	On	On	On	On				
Watchdog timer (WDT)	Available	Available	Available	Off	Off				

Т	able	8-3	Ρ	ower	Modes
	abie	0-5.		OWEI	Modes

(1) "Available" indicates that the specific IP or feature can be enabled by user application in the corresponding device operating modes. "On" indicates that the specific IP or feature is turned on irrespective of the user application configuration of the device in the corresponding device operating mode. "Off" indicates that the specific IP or feature is turned off and not available for the user application in the corresponding device operating mode.

(2) Software-based retention of CPU registers with context save and restore when entering and exiting standby power mode

In the **Active** mode, both of MCU and AON power domains are powered. Clock gating is used to minimize power consumption. Clock gating to peripherals/subsystems is controlled manually by the CPU.

In **Idle** mode the CPU is in sleep but selected peripherals and subsystems (such as the radio) can be active. Infrastructure (Flash, ROM, SRAM, bus) clock gating is possible depending on state of the DMA and debug subsystem.

In **Standby** mode, only the always-on (AON) domain is active. An external wake-up event, RTC event, or comparator event (LP-COMP) is required to bring the device back to active mode. Pin Reset will also drive the device from Standby to Active. MCU peripherals with retention do not need to be reconfigured when waking up again, and the CPU continues execution from where it went into standby mode. All GPIOs are latched in standby mode.

In **Shutdown** mode, the device is entirely turned off (including the AON domain), and the I/Os are latched with the value they had before entering shutdown mode. A change of state on any I/O pin defined as a *wake from shutdown pin* wakes up the device and functions as a reset trigger. The CPU can differentiate between reset in this way and reset-by-reset pin or power-on reset by reading the reset status register. The only state retained in this mode are the latched I/O state, 3V register bank, and the flash memory contents.

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Note

The power, RF and clock management for the TTC2340R device require specific configuration and handling by software for optimized performance. This configuration and handling is implemented in the TI-provided drivers that are part of the TTC2340R software development kit (SDK). Therefore, TI highly recommends using this software framework for all application development on the device. The complete SDK with FreeRTOS, device drivers, and examples are offered free of charge in source code.

8.12 Clock Systems

The TTC2340R device has the following internal system clocks.

The 48MHz HFCLK is used as the main system (MCU and peripherals) clock. This is driven by the internal 48MHz RC Oscillator (HFOSC), which can track its accuracy against an external 48MHz crystal (HFXT). Radio operation requires an external 48MHz crystal.

The 32.768kHz LFCLK is used as the internal low-frequency system clock. It is used for the RTC, the watchdog timer (if enabled in standby power mode), and to synchronize the radio timer before or after Standby power mode. LFCLK can be driven by the internal 32.8kHz RC Oscillator (LFOSC), a 32.768kHz watch-type crystal, or clock input in LFXT bypass mode. When using a crystal or the internal RC oscillator, the device can output the 32kHz LFCLK signal to other devices, thereby reducing the overall system cost.

8.13 Network Processor

Depending on the product configuration, the TTC2340R device can function as a wireless network processor (WNP), a device running the wireless protocol stack with the application running on a separate host MCU, or as a system-on-chip (SoC), with the application and protocol stack running on the system CPU inside the device.

In the first case, the external host MCU communicates with the device using SPI or UART. In the second case, the application must be written according to the application framework supplied with the wireless protocol stack.



9 Application, Implementation, and Layout

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Reference Designs

The following reference designs should be followed closely when implementing designs using the TTC2340R devices.

Special attention must be paid to RF component placement, decoupling capacitors, and DCDC regulator components, as well as ground connections for all of these.

LP-EM-TTC2340R5 Design Files	The TTC2340R5 LaunchPad Design Files contain detailed schematics and layouts to build application-specific boards using the TTC2340R devices in the 5mm x 5mm RKP package.
LP-EM-TTC2340R5- RGE-4x4-IS24 Design Files	The TTC2340R5 RGE 4x4 LaunchPad Design Files contain detailed schematics and layouts to build application-specific boards using the TTC2340R devices in the 4mm x 4mm RGE package. The TTC2340R5x and TTC2340R2x devices in RGE packages are pin-to-pin compatible.
Sub-1 GHz and 2.4 GHz Antenna Kit for LaunchPad™ Development Kit and SensorTag	 The antenna kit allows real-life testing to identify the optimal antenna for your application. The antenna kit includes 16 antennas for frequencies from 169MHz to 2.4GHz, including: PCB antennas Helical antennas Chip antennas Dual-band antennas for 868MHz and 915MHz combined with 2.4GHz

The antenna kit includes a JSC cable to connect to the Wireless MCU LaunchPad Development Kits and SensorTags.

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9.2 Junction Temperature Calculation

This section shows the different techniques for calculating the junction temperature under various operating conditions. For more details, see Semiconductor and IC Package Thermal Metrics.

There are two recommended ways to derive the junction temperature from other measured temperatures:

1. From package temperature:

$$T_{J} = \psi_{JT} \times P + T_{case}$$
(1)

2. From board temperature:

$$T_{J} = \psi_{JB} \times P + T_{board}$$
(2)

P is the power dissipated from the device and can be calculated by multiplying current consumption with supply voltage. Thermal resistance coefficients are found in *Thermal Resistance Characteristics*.

Example:

In this example, we assume a simple use case where the radio is transmitting continuously at 0dBm output power. Let us assume we want to maintain a junction temperature equal or less than 85° C and the supply voltage is 3V. Using Equation 1, the temperature difference between the top of the case and junction temperature is calculated. To calculate P, look up the current consumption for Tx at 85° C. At 85° C the current consumption is approximately 5.5mA. This means that P is 5.5mA × 3V = 16.5mW.

The maximum case temperature to maintain and junction temperature of 85°C is then calculated as:

$$T_{case} < T_j - 0.4^{\circ C} / W \times 23.4 mW = 84.99^{\circ C}$$
 (3)

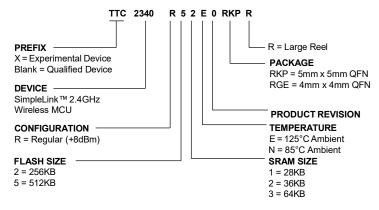
For various application use cases, current consumption for other modules may have to be added to calculate the appropriate power dissipation. For example, the MCU may be running simultaneously as the radio, peripheral modules may be enabled, and so on. Typically, the easiest way to find the peak current consumption, and thus the peak power dissipation in the device, is to measure as described in the Measuring CC13xx and CC26xx Current Consumption application report.



10 Device and Documentation Support

TTC offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed as follows.

10.1 Device Nomenclature

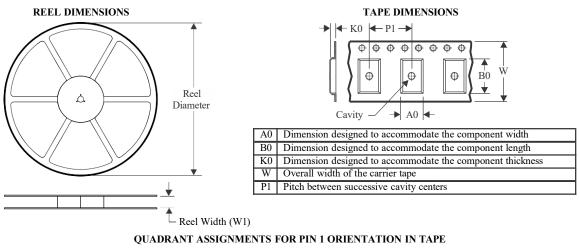


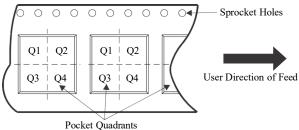
PACKAGE MATERIALS INFORMATION



6-Feb-2025

TAPE AND REEL INFORMATION



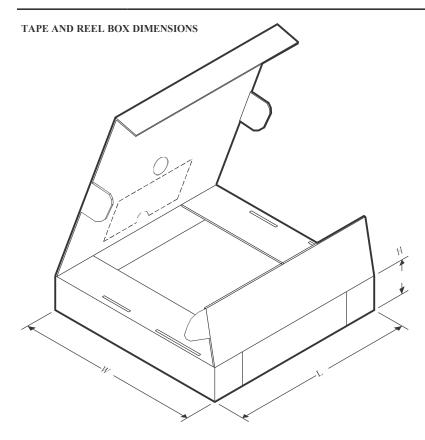


*All dimensions are nomina	l											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TTC2340R52E0RGEF	VQFN	RGE	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
TTC2340R52E0RKPR	VQFN	RKP	40	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION



6-Feb-2025



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TTC2340R52E0RGER	VQFN	RGE	24	3000	367.0	367.0	35.0
TTC2340R52E0RKPR	VQFN	RKP	40	3000	367.0	367.0	35.0

Pack Materials-Page 2

RKP 40

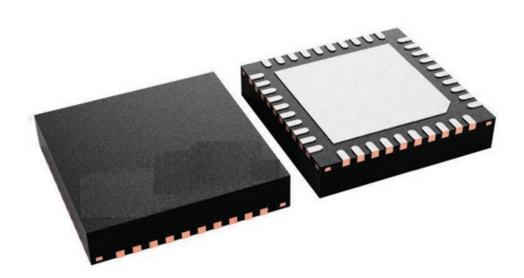
5 x 5, 0.4 mm pitch

GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



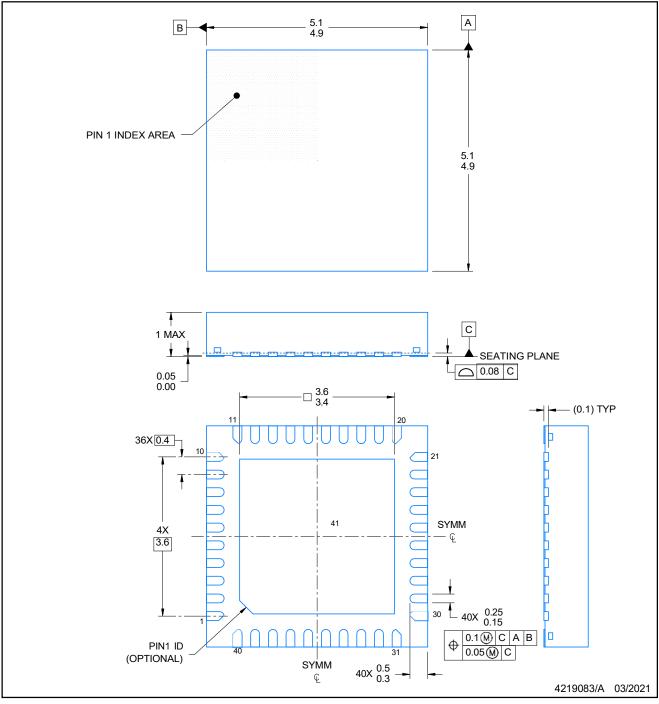
4229305/A

RKP0040B

PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD

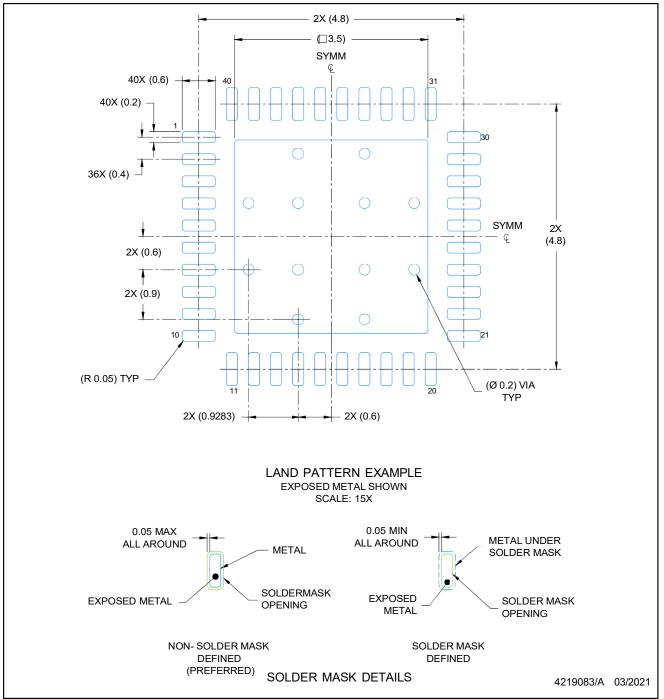


RKP0040B

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD

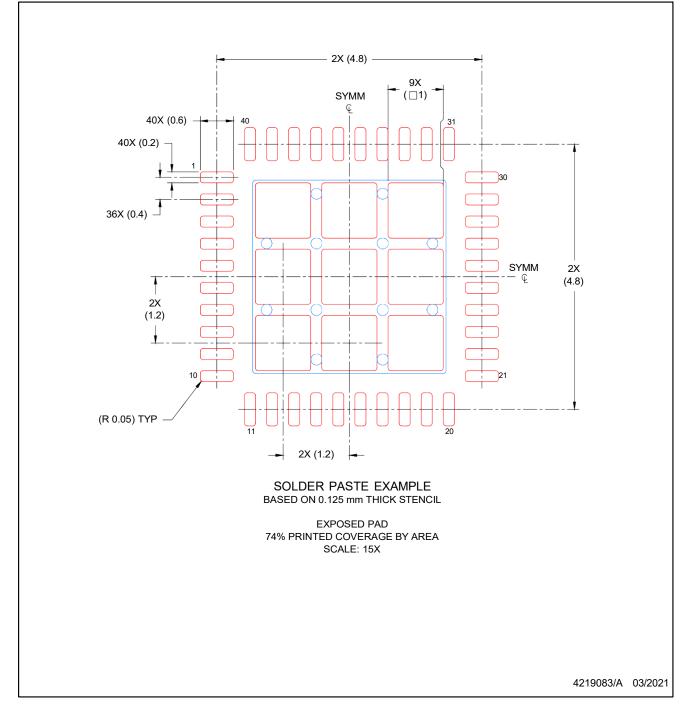


RKP0040B

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

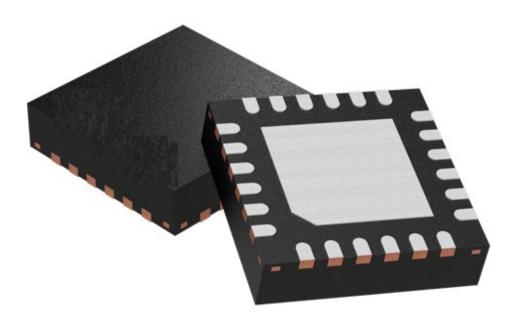
PLASTIC QUAD FLATPACK- NO LEAD



GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4204104/H

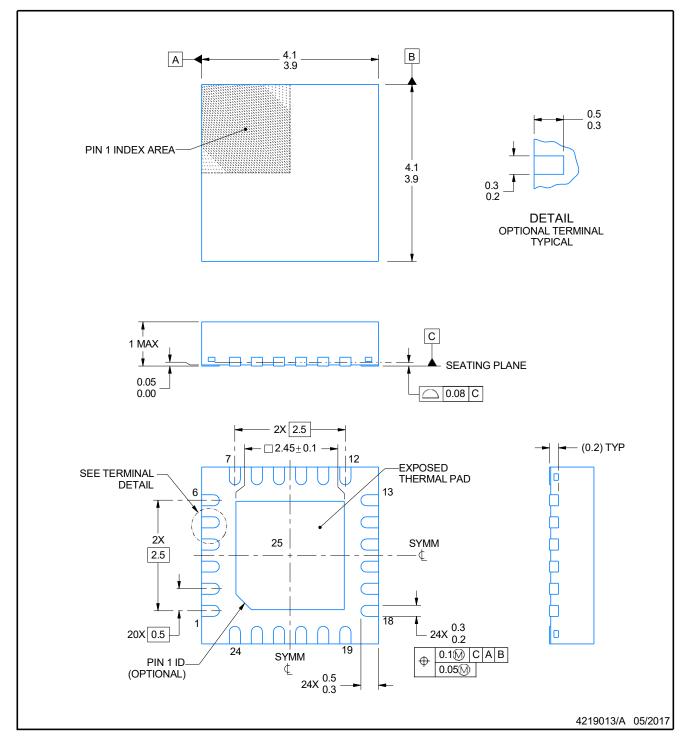
RGE0024B



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

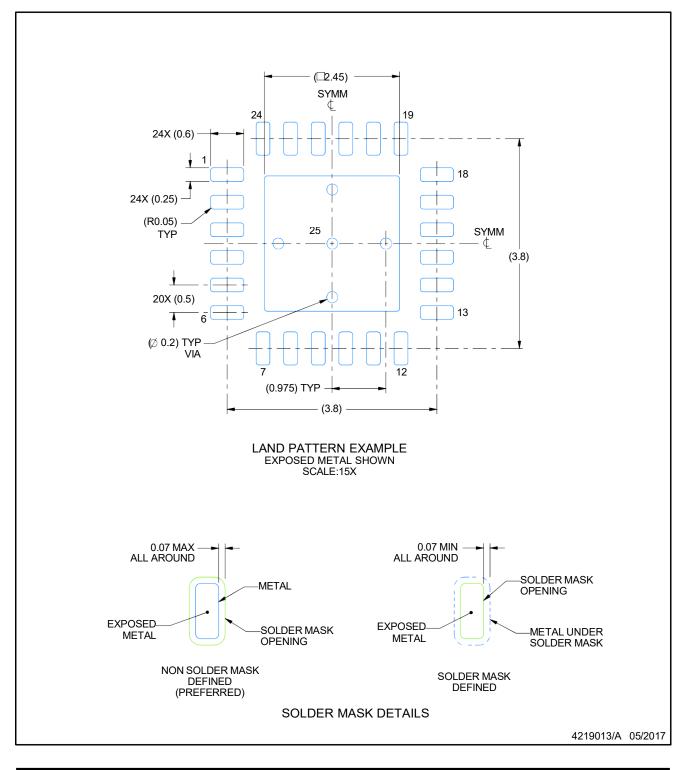


RGE0024B

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

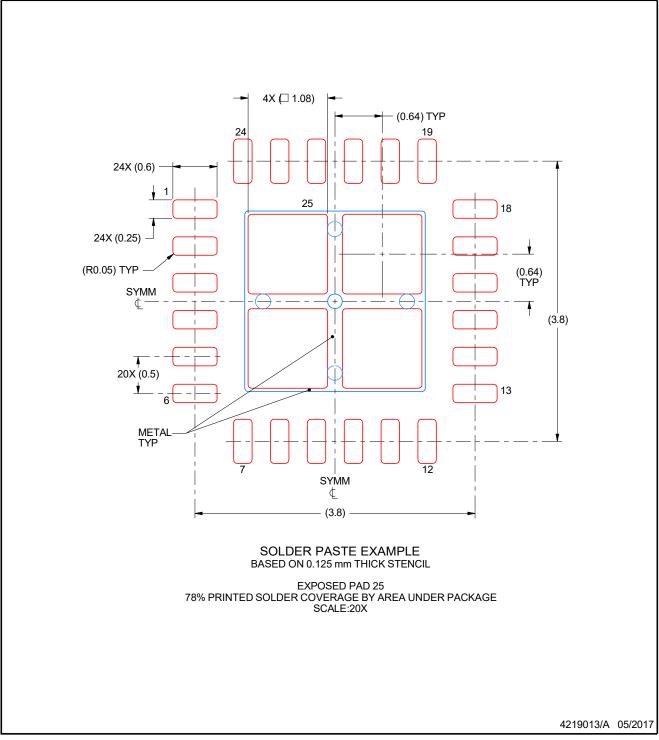


RGE0024B

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

1.Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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